



17TH ADVANCED BEAM DYNAMICS WORKSHOP ON

FUTURE LIGHT SOURCES

X-ray Optics

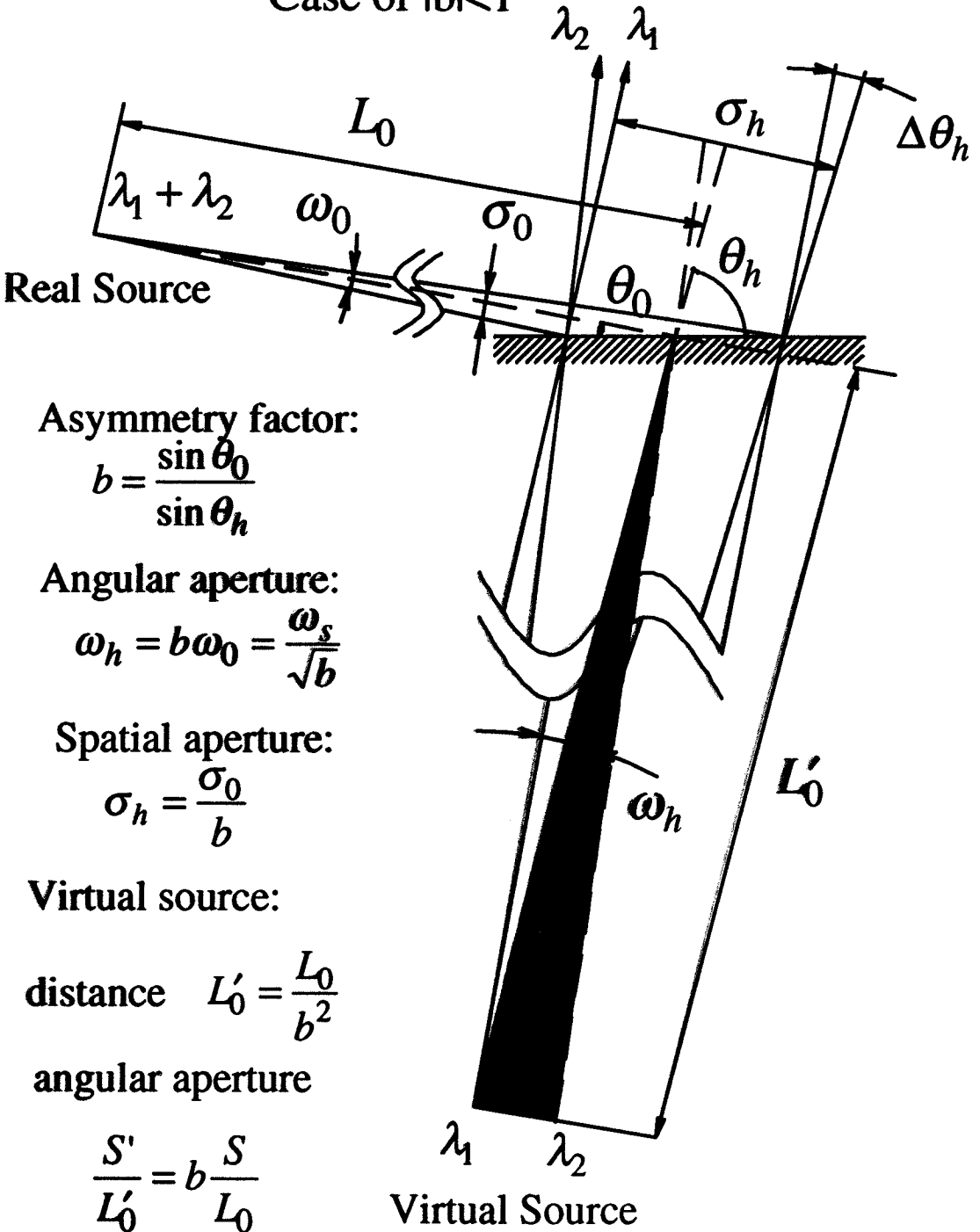
A. Freund, ESRF

APRIL 6-9, 1999

ARGONNE NATIONAL LABORATORY, ARGONNE, IL U.S.A.

Optical Properties of a Single Asymmetrically Cut Crystal

Case of $|b| < 1$



Courtesy: A. SOUVOROV (ESRF)

EXAMPLES: Si AND DIAMOND AT $1.5\text{\AA}^*$

Crystal	$d(\text{\AA})$	θ_B	θ_i	θ_e	b	foot-print (mm)	$\Delta E/E$	$t_{\text{ext}}(\mu\text{m})$	$t_{\text{abs}}(\mu\text{m})$
Si(220)	1.9200	22.99°	0.1°	45.88°	411	85.9	1.2×10^{-3}	0.10	3×10^{-4} 0.124
C*(111)	2.0593	21.36°	0.1°	42.62°	388	85.9	1.2×10^{-3}	0.11	0.65 2.33

Power spreading factor : $\approx 600!$

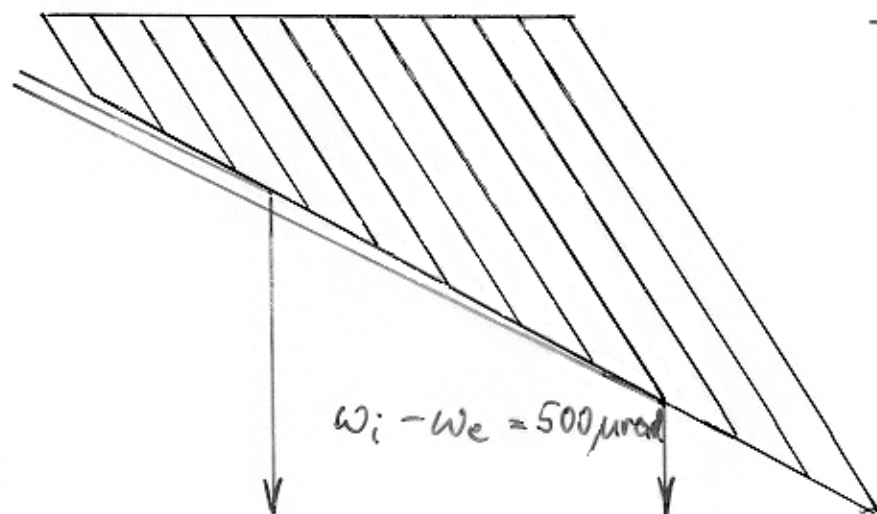
full range reflected

Surface should be very smooth and precisely oriented : feasible !

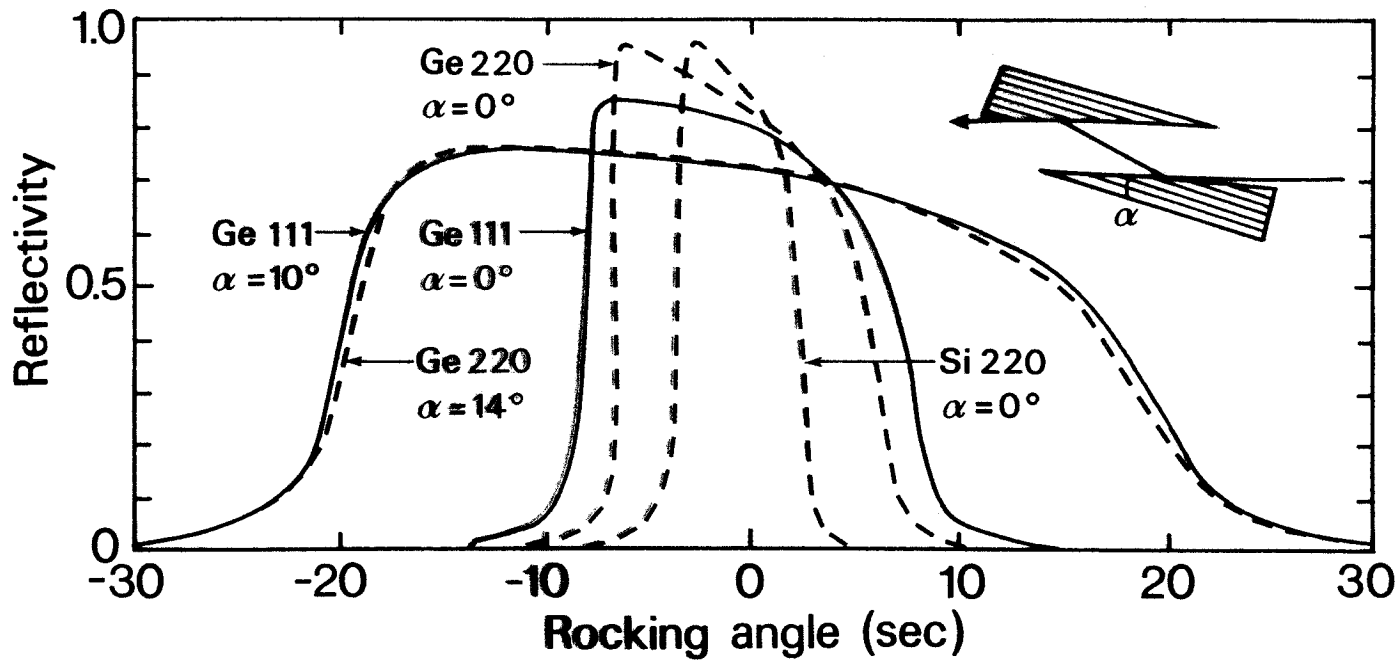
* No refraction corrections of the Bragg angle included.

Further possibilities:

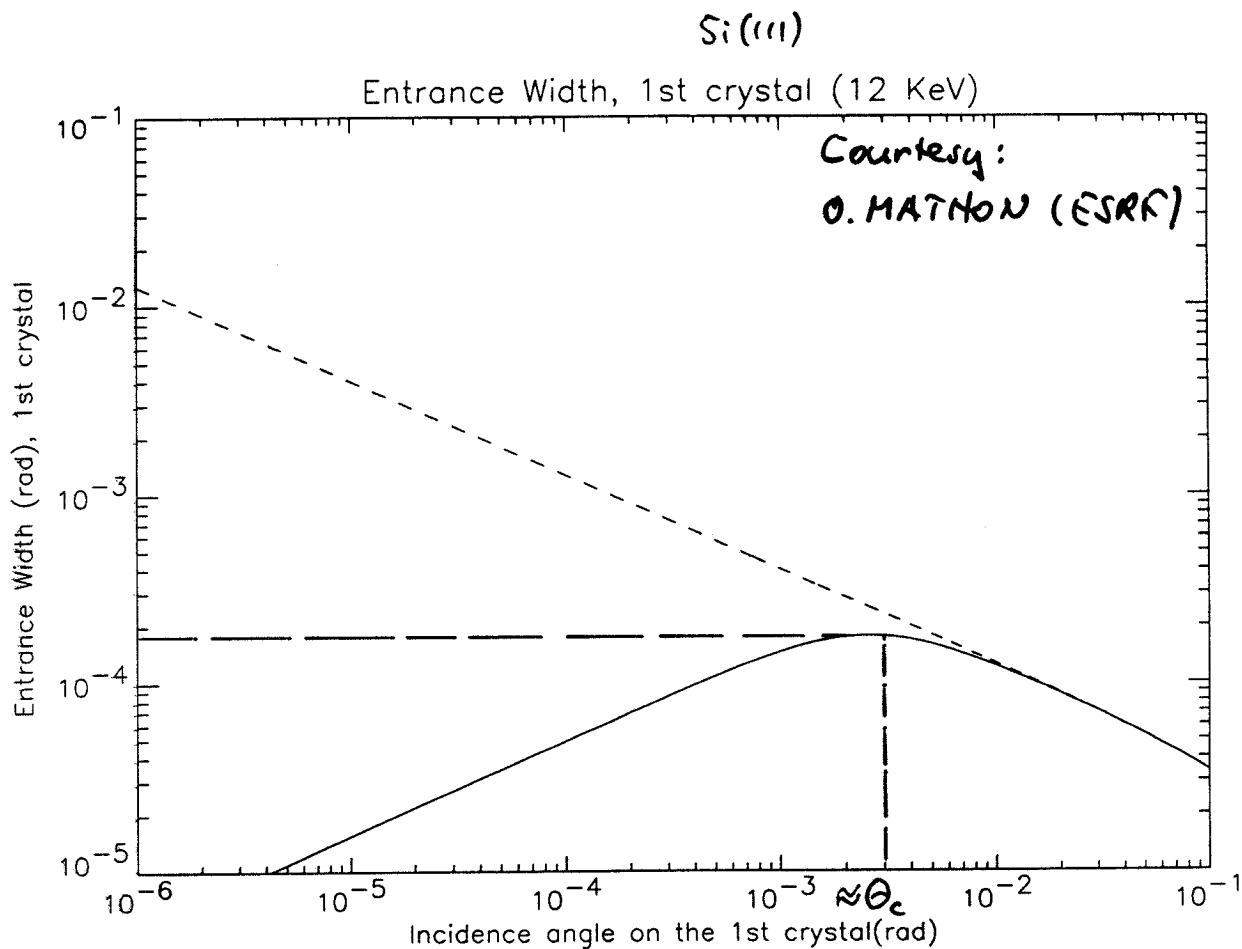
- inclined geometry
- Borrmann effect (anomalous transmission)
- long beamlines



From:
A. Freund
SLAC Workshop (1997)



From: MATSUSHITA & HASHIZUME (1983)



Symmetric

$$\omega_D = \frac{\Delta E}{E} + g\theta = 2.3 \times 10^{-5} \text{ rad} \quad \frac{\Delta E}{E} = 1.4 \times 10^{-4}$$

Asymmetric

$$\omega_{A,i} = \omega_D / \sqrt{b}; \text{ max : } 2 \times 10^{-4} \text{ rad} \quad \left(\frac{\Delta E}{E} \right)_{\text{max}} = 1.4 \times 10^{-3}$$

$$b = \frac{\sin \theta - \alpha}{\sin \theta + \alpha} \Rightarrow b_{\text{min}} \approx \frac{1}{100}$$

$$\omega_{A,e} = \omega_D \sqrt{b}; \text{ min} = 2 \times 10^{-6} \text{ rad};$$

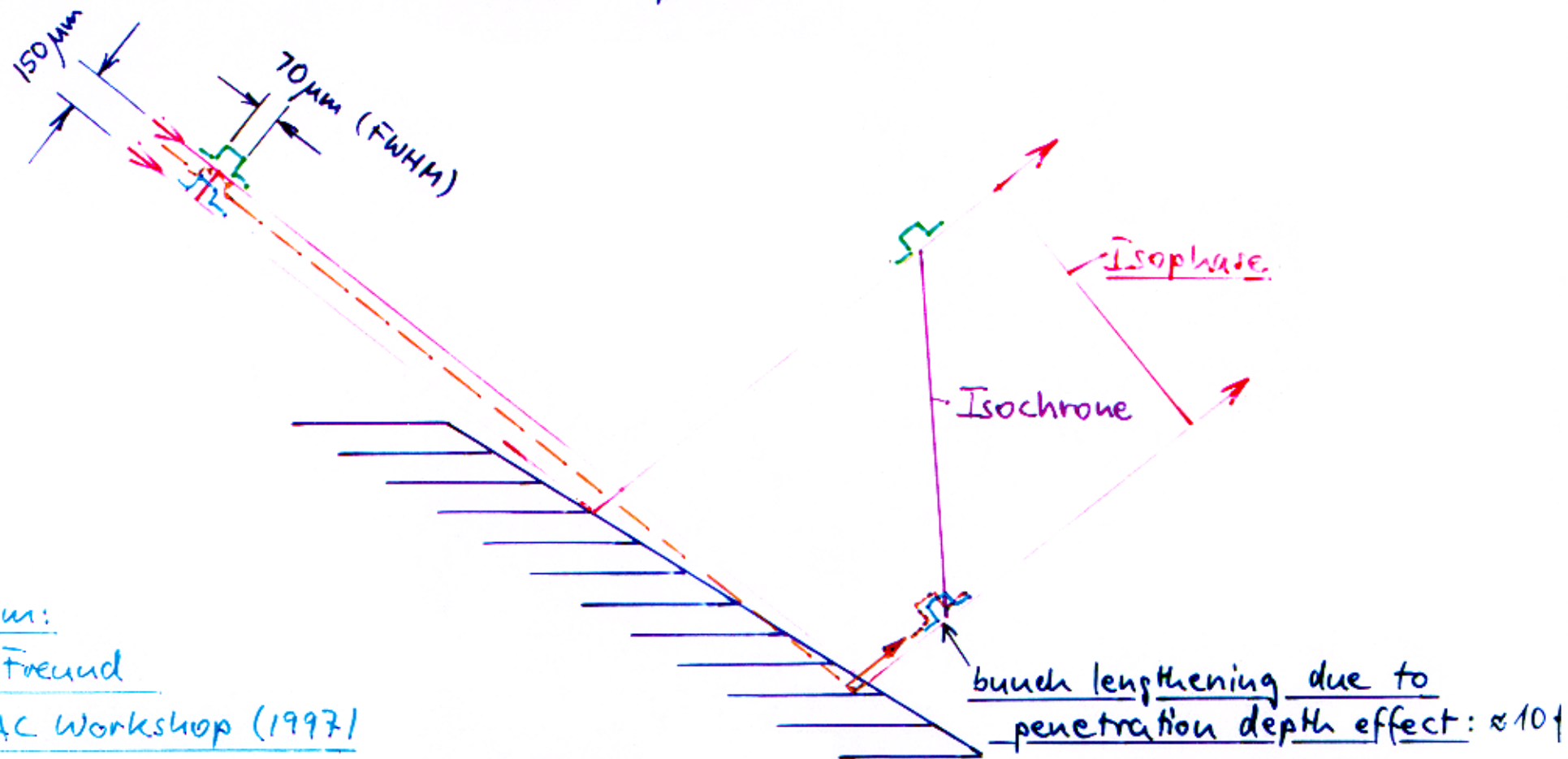
ISOPHASES AND ISOCHRONES

Possibilities:

- Time dispersion
- Time focusing
- Bunch lengthening
- Bunch compression

In connection with:

- Time-Energy dependence of source
- Gradient crystals

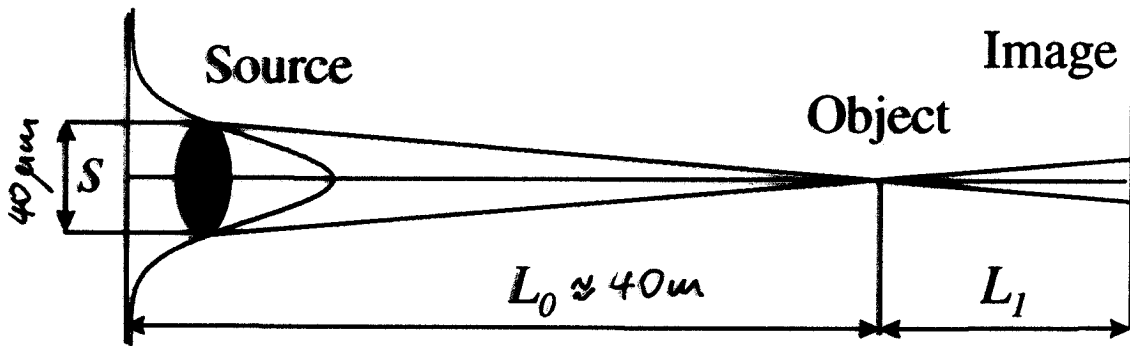


From:

A. Freund

SLAC Workshop (1997)

Introduction



While distance L_0 is large,

COHERENCE $\longrightarrow$ **SPATIAL + TEMPORAL**

SPATIAL COHERENCE
is inverse to the source size

$$\propto \frac{\lambda}{S} L_0 \approx 100 \mu m$$

TEMPORAL COHERENCE
is inverse to the spectral width

$$\propto \frac{\lambda^2}{\Delta \lambda}$$

Can we control coherence?

TEMPORAL COHERENCE $\longrightarrow$ crystal monochromators
provide $\Delta \lambda / \lambda \sim 10^{-4} - 10^{-6}$

SPATIAL COHERENCE $\longrightarrow$ distance, filters, mirrors

**The suitability of asymmetrically cut crystals
to control spatial coherence:
true or false ?**

Courtesy: A. SOUVOROV (ESRF)

Requirements on quality of monochromators

II. Tolerance on miscut in (+,-) asymmetrical reflection

$$|\Delta\varphi| = \frac{\eta\omega_s \sin^2(\theta_B - \varphi)}{\sqrt{b_1}\omega_c \sin 2\theta_B}$$

Example:

The same parameters as before, plus $\varphi=8.48^\circ$ which gives $b_1=4\cdot 10^{-2}$, $b_2=25$

Then

$$|\Delta\varphi| < 10^{-5} \text{ rad (which is } \sim 2'')$$

III. Tolerance on temperature difference in (+,-) asymmetrical reflection

$$|\Delta T| \leq \frac{\eta\omega_s \sin^2(\theta_B - \varphi)}{\alpha_T \sqrt{b_1}\omega_c \sin 2\varphi \tan \theta_B}$$

Example:

The same parameters as before, plus

$$\alpha_T = 2.5 \cdot 10^{-6} \text{ K}^{-1}$$

Then

$$|\Delta T| < 30^\circ$$

Courtesy: A. SOUVOROV (ESRF)

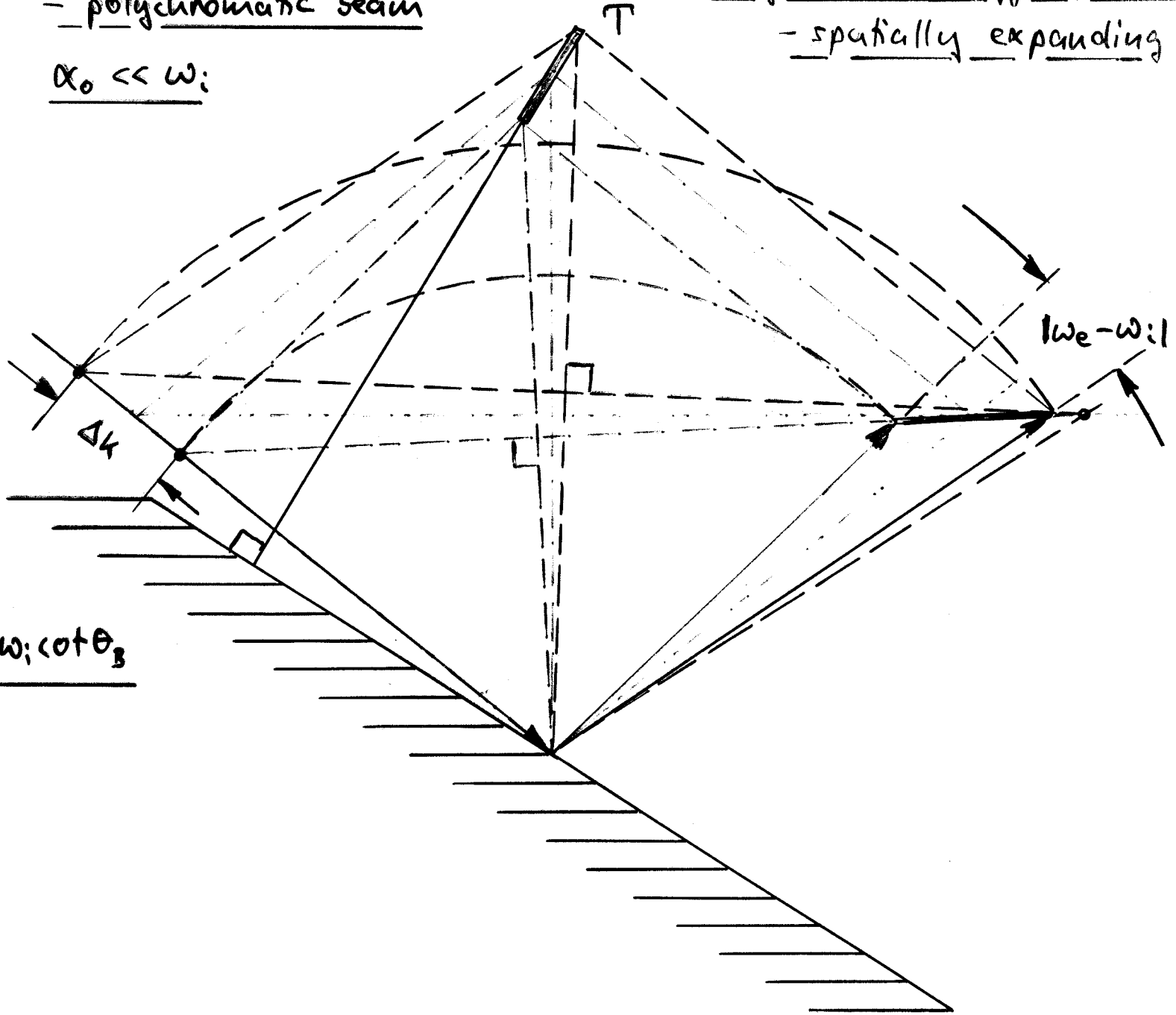
RECIPROCAL SPACE DIAGRAM

- polychromatic beam

$\alpha_0 \ll \omega_i$

Asymmetric Bragg reflection

- spatially expanding case



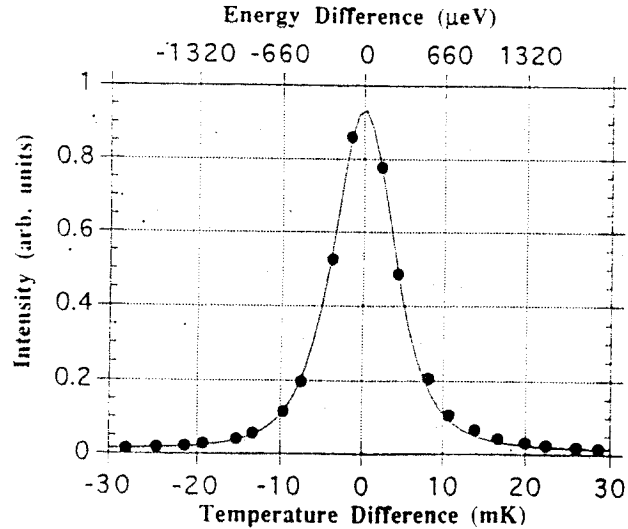
$$\frac{\Delta k}{k} = w_i \cot \theta_B$$

SOME CRYSTAL PARAMETERS AT 8 KEV

Material (h k l)	$d_H = \frac{a}{2} \lambda_{max}$ (Å)	$r_0 F_H r_e^{-M/v_0}$ (10^{-14} cm^{-2})	darwin width ω_H (μrad)	energy resolution ϵ_H (10^{-6})	extinction thickness t_e (μm)	absorption t_a (μm)	
Be (002)	1.7916	5.59	10.7	22.8	5.0	1200	
Be (110)	1.1428	4.27	6.49	7.1	10.3	1874	
C* (111) (diamond)	2.0593	11.1	24.1	59.7	2.20	250	
C* (220)	1.2611	9.55	14.9	19.3	4.16	408	
Si (111)	3.1354	10.82	34.3	135	1.48	8.7	most commonly used
Si (220)	1.9200	12.29	25.3	57.7	2.12	14.2	
Ge (111)	3.2663	23.06	76.0	313	0.66	2.94	for high energies
Ge (220)	2.0002	27.51	58.5	140	0.91	4.79	

SINGLE CRYSTAL PERFECTION

SILICON

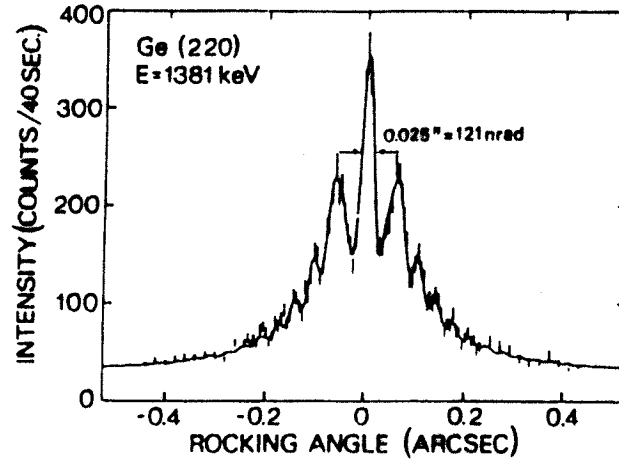


Backscattering Si (13,13,13)
rocking curve, T-scan at 26 keV
0.5 μeV! $\Delta E/E = 2 \cdot 10^{-8}$ (FWHM) $\approx \Delta\alpha/\alpha$
(best value ever achieved)

Sette et al., ESRF Report (1995)

improved to $\Delta E/E = 9 \cdot 10^{-9}$!

GERMANIUM

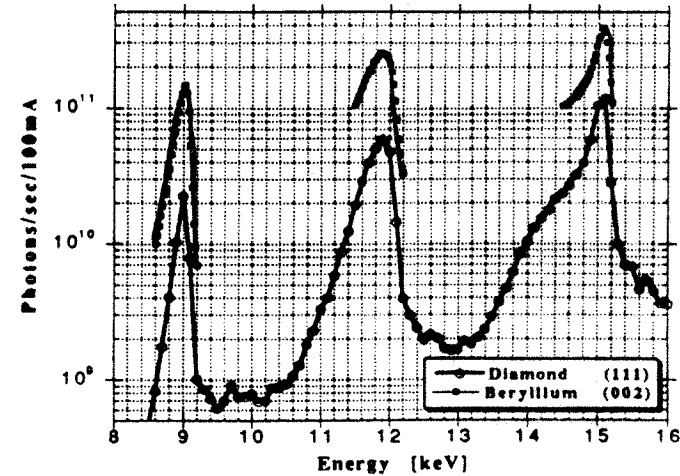


Ge double crystal Laue
diffraction pattern at 1.4 MeV.
Excess width: $3 \cdot 10^{-8}$ rad.
(best value ever achieved)

Freund, RSI 63, 414 ('92)

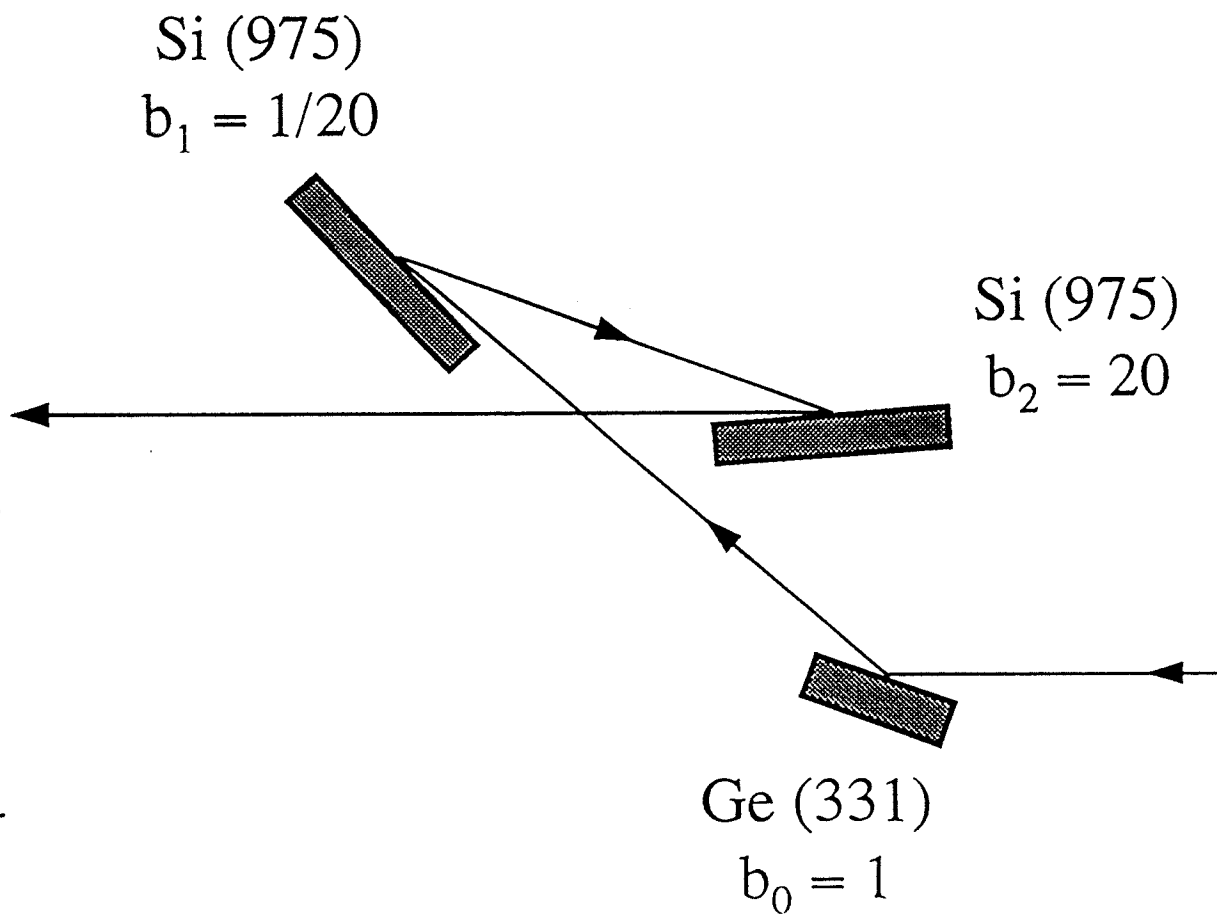
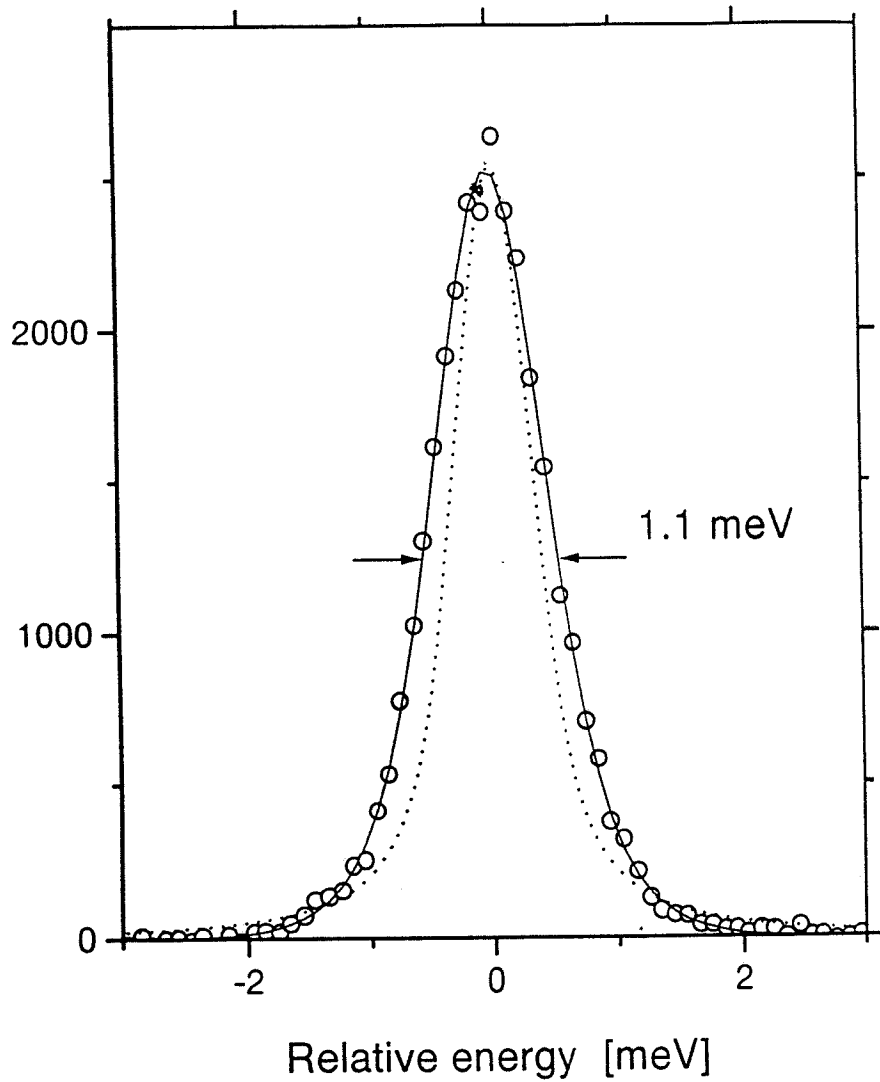
Dewey et al., PR B50, 2800 ('94)

BERYLLIUM, DIAMOND



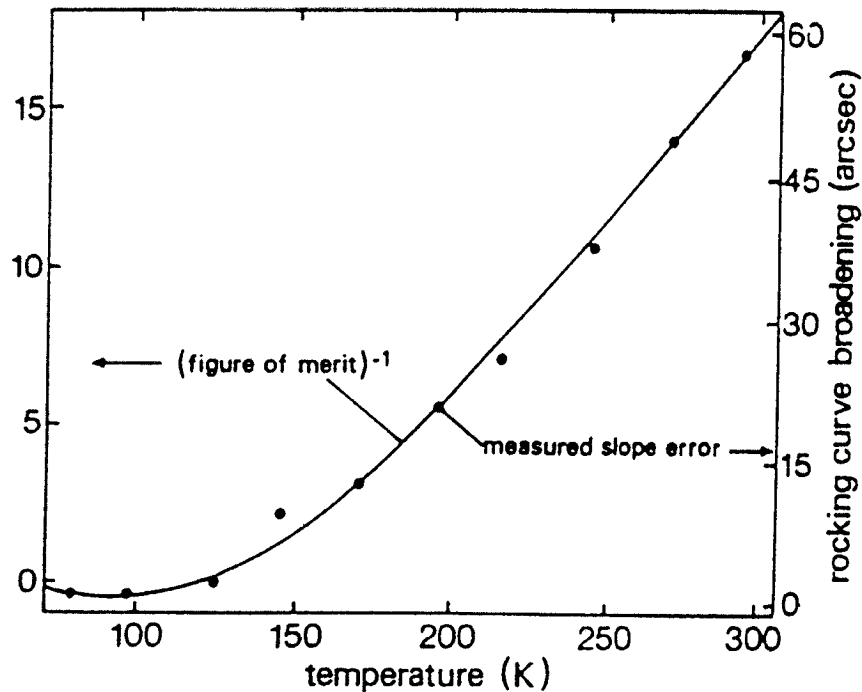
ID10 undulator spectra
recorded with diamond
and Be single crystals.
0.5 x 0.5 mm² at 44 m.

Grübel et al. J.Phys. C9, 27 ('94)



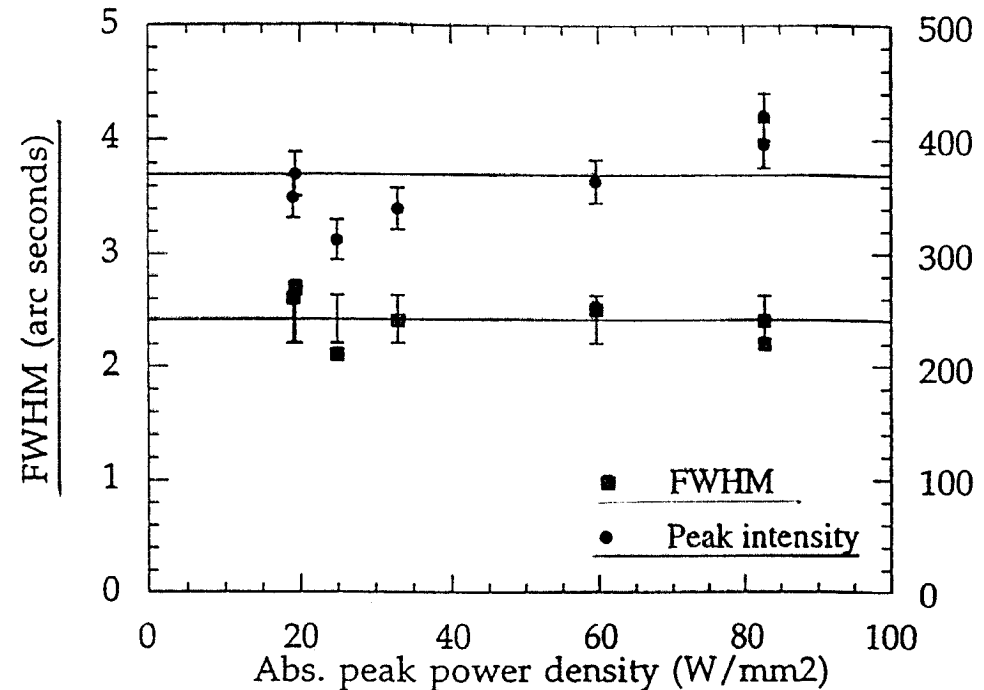
Courtesy: A. CHUMAKOV (ESRF)

Cryogenic cooling for crystal (and multilayer substrates)



Thick crystal, side cooled
 $P_s = 150 \text{ W/mm}^2$, $P_t = 80 \text{ W}$
 NSLS X25

A. Freund, *Rev Sci. Inst.*, 63, (1992)
 G. Marot et al. *Rev Sci. Inst.*, 63, (1992)



Thin crystal, direct cooled
 $P_s = 415 \text{ W/mm}^2$, $P_t = 167 \text{ W}$
 ESRF BL3

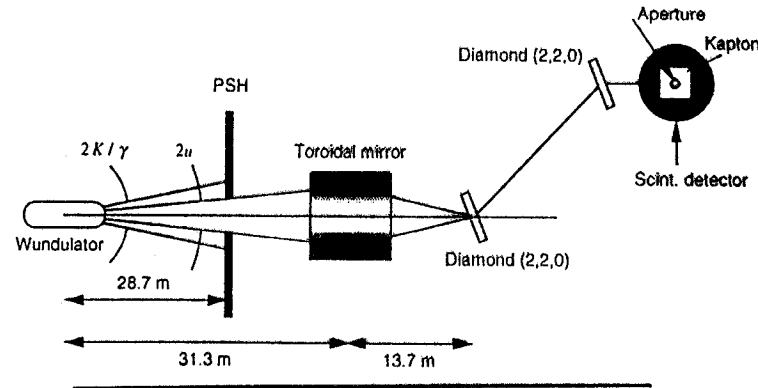
peak power density $\approx 20 \text{ kW/mm}^2$

A. Rogers et al., *Rev Sci. Inst.*, 66, (1995)

Diamond single crystal - the ultimate



heat load tests @ ESRF on wundulator source BL3/ID9

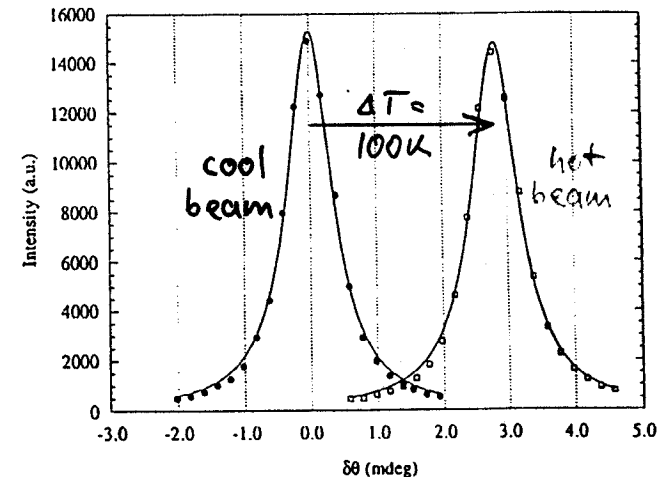
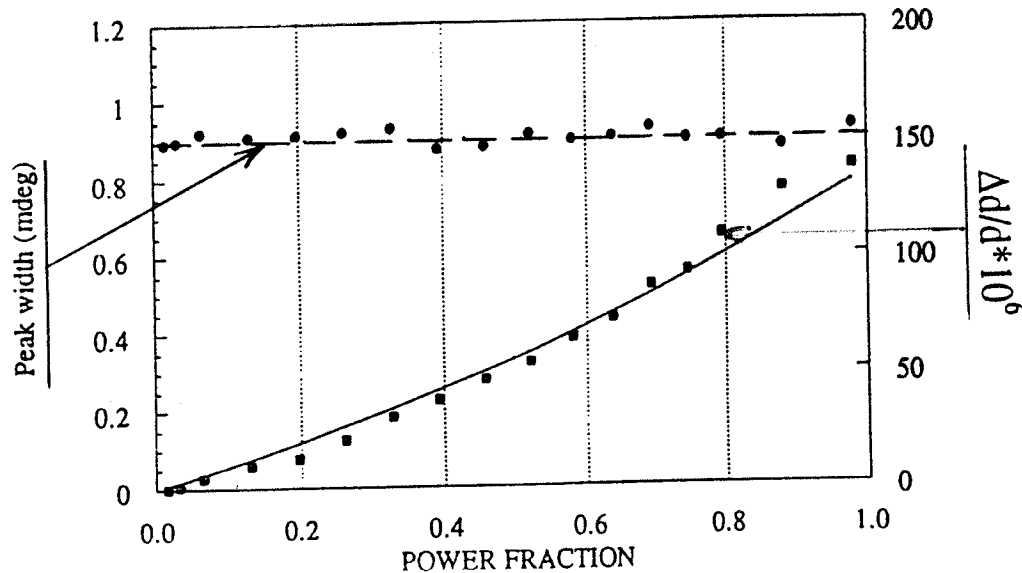


the beam is focused by the toroidal mirror onto a $4 \times 8 \times 0.1 \text{ mm}^3$ synthetic diamond crystal (Laue case)
(supplied by F. Sellschop, University of Johannesburg)

➔ incident [spot $0.2(\text{h}) \times 0.4(\text{v}) \text{ mm}^2$]: $P_i = 280 \text{ W}$ $\Rightarrow P_s = 3500 \text{ W/mm}^2$

➔ absorbed: $P_t = 8.7 \text{ W}$ (3.1%) and $P_s = 109 \text{ W/mm}^2$

Heat Flux 50 x that on
the sun's surface !!!

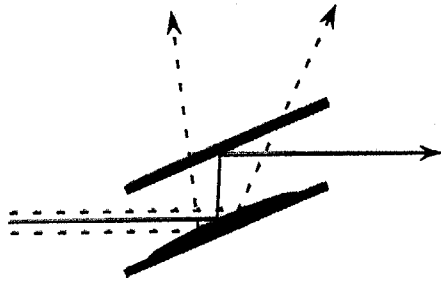


from J. Als-Nielsen et al., NIM B, 94, (1994)

Heat Problem : Crystal case



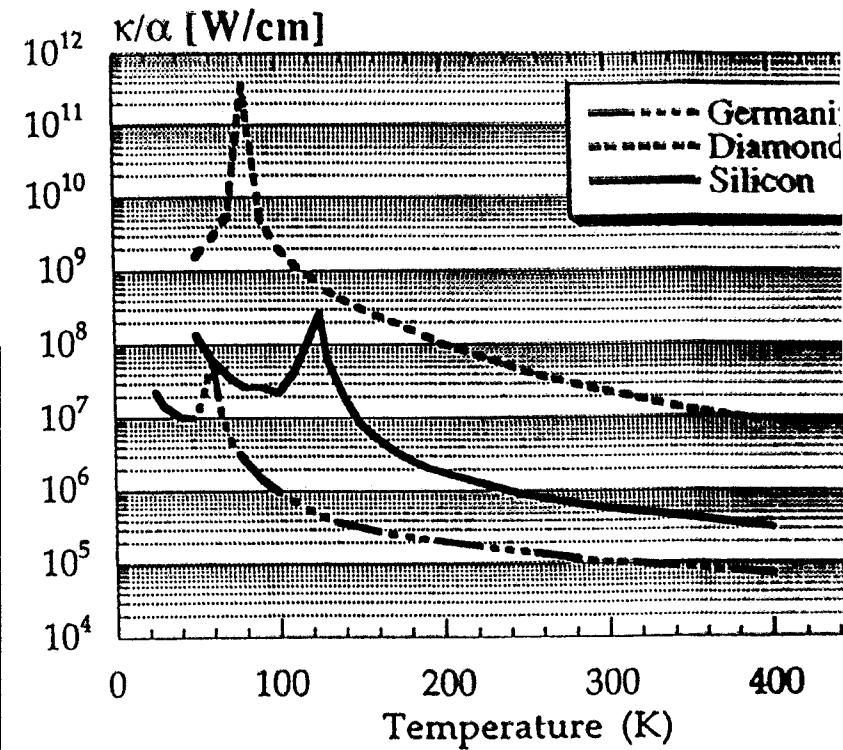
- usually P_s very high $\Rightarrow \Delta_{bump} > \Delta_{bending}$: for undulator radiation.



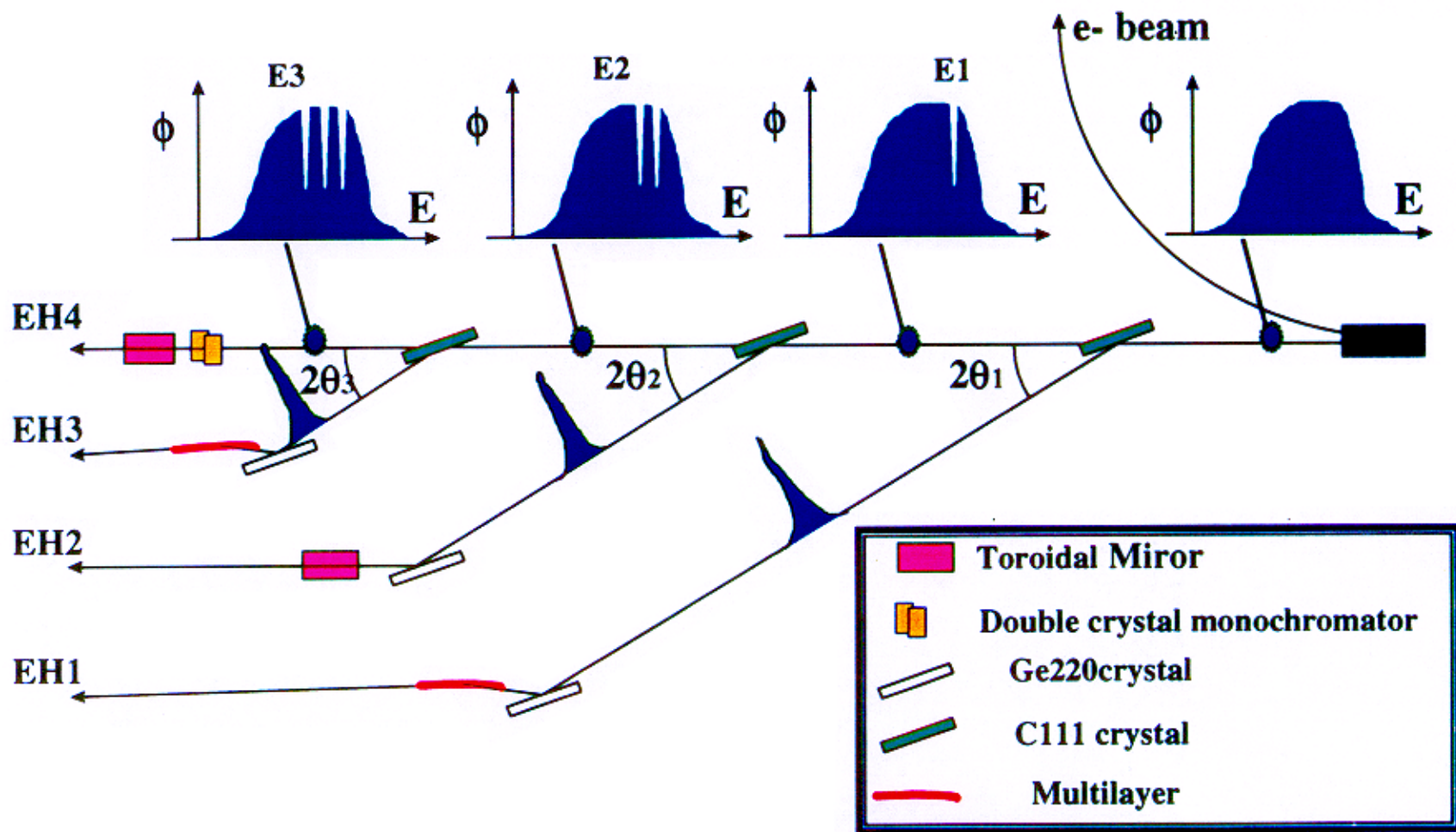
$$\Delta_{bump} \propto \frac{\alpha}{\kappa} G P e^{-\mu x} \begin{cases} \mu x < 1 \Rightarrow x = t \\ \mu x > 1 \Rightarrow x = t_{abs} \end{cases}$$

- ↪ one reflection : increase of beam divergence and bandpass
- ↪ double reflection : loss of transmission

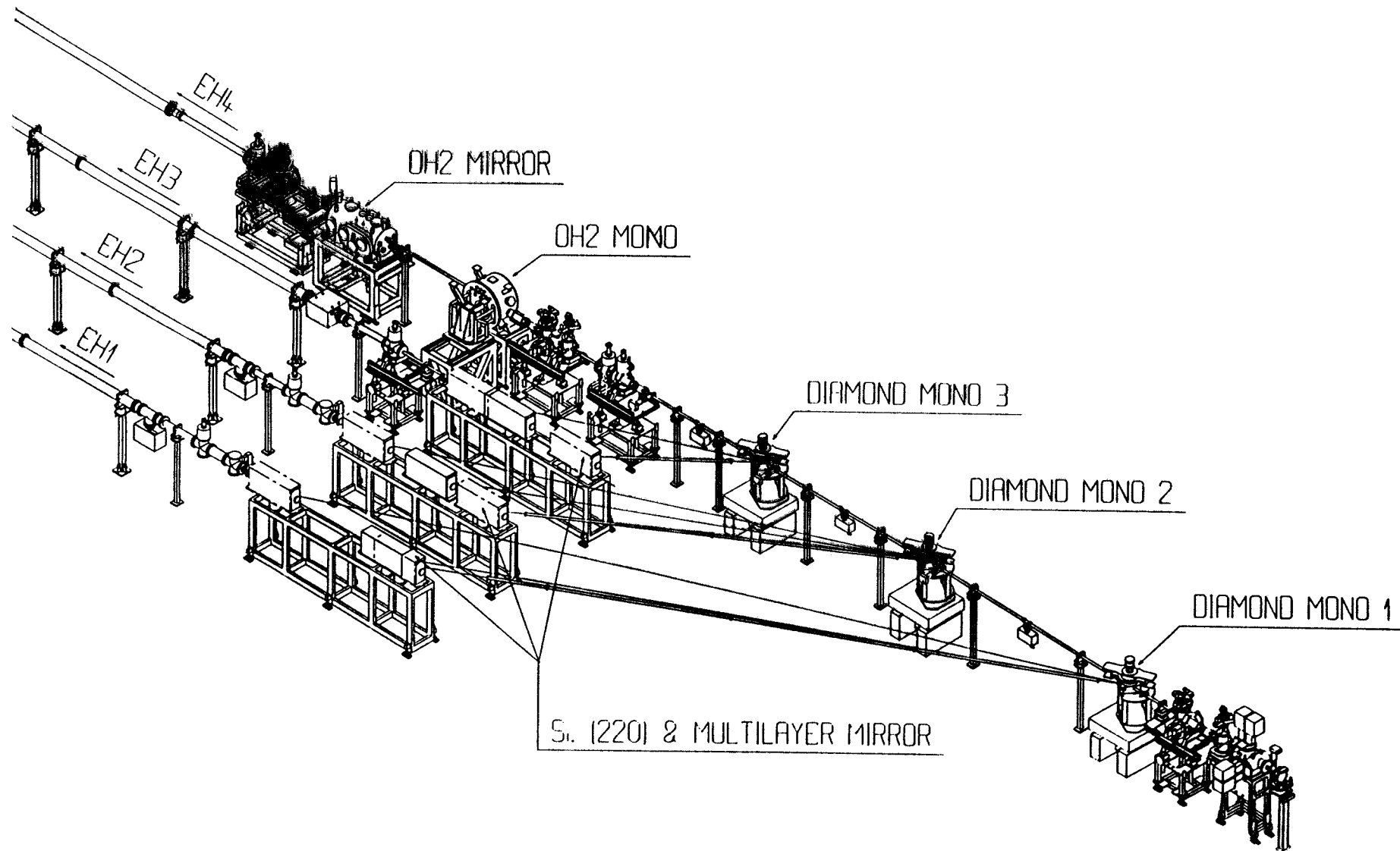
Material	Be	C*	Si	Ge
Crystal	hcp	diamond	diamond	diamond
μ @8keV [cm^{-1}]	3.5% 1.8	14% 7.5	94% 141	99.97% 402
κ @297K [$\text{Wcm}^{-1}\text{K}^{-1}$]	1.94	23	1.5	0.64
α @297K [10^{-6}K^{-1}]	7.7	1.1	2.4	5.6
$\kappa/\mu\alpha$ @ 297K [MK]	0.14	2.80	$5 \cdot 10^{-3}$	$3 \cdot 10^{-4}$
@ 77K [MK]	11	120	$2 \cdot 10^{-1}$	$7 \cdot 10^{-3}$



ID14-Quadriga principle



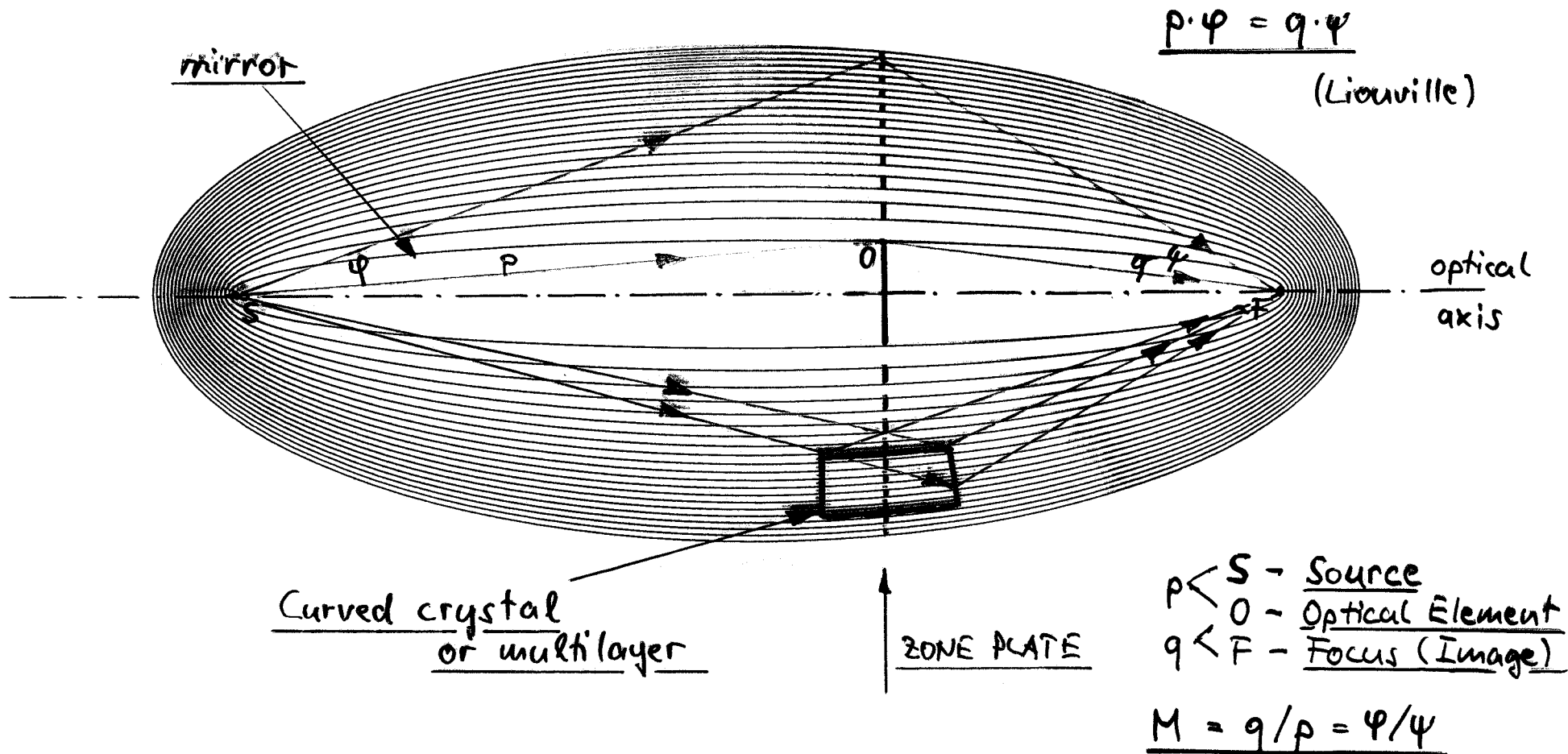
Courtesy: S. WAKATSUKI (ESRF)



Courtesy: S. WAKATSUKI (ESRF)

FOCUSING

⇒ All imaging elements can be seen as sections of holograms of a point with a spherical reference wave.

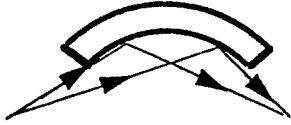
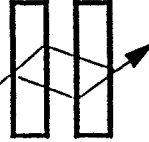
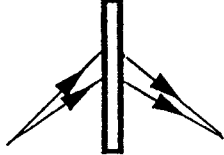
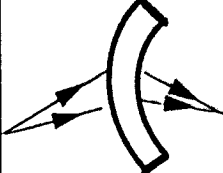
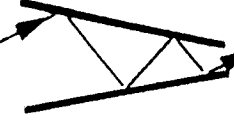
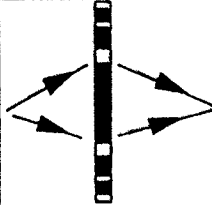
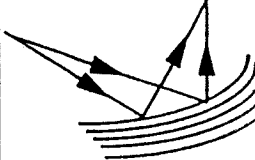


⇒ The isophase figures are confocal ellipses
 (see also: Spiller "Soft X-ray Optics", SPIE, 1994.)

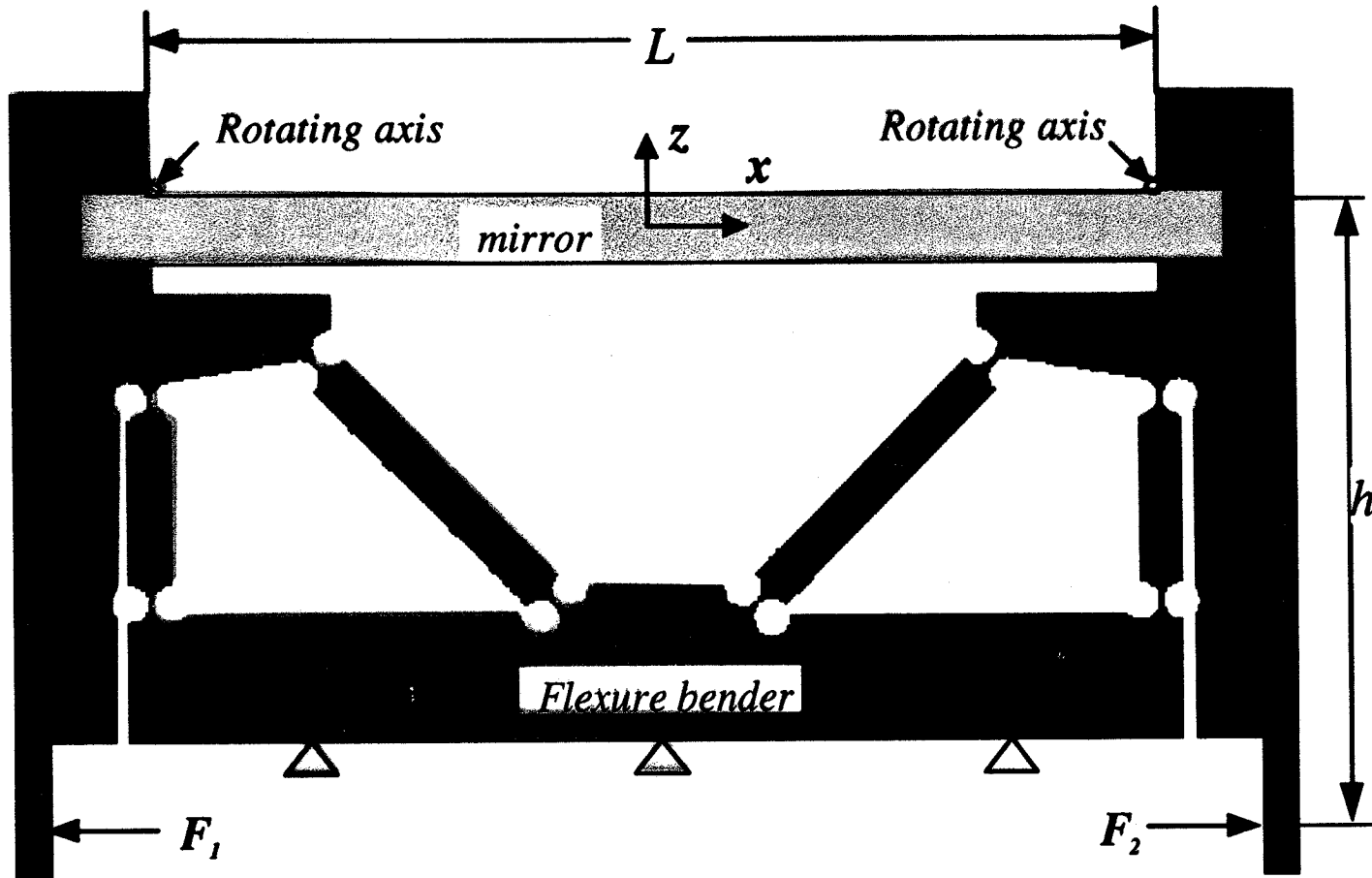
FOCUSING OPTICS FOR HARD X-RAYS

$3 \text{ keV} < E < 100 \text{ keV}$

(after Snigirev, 1995)

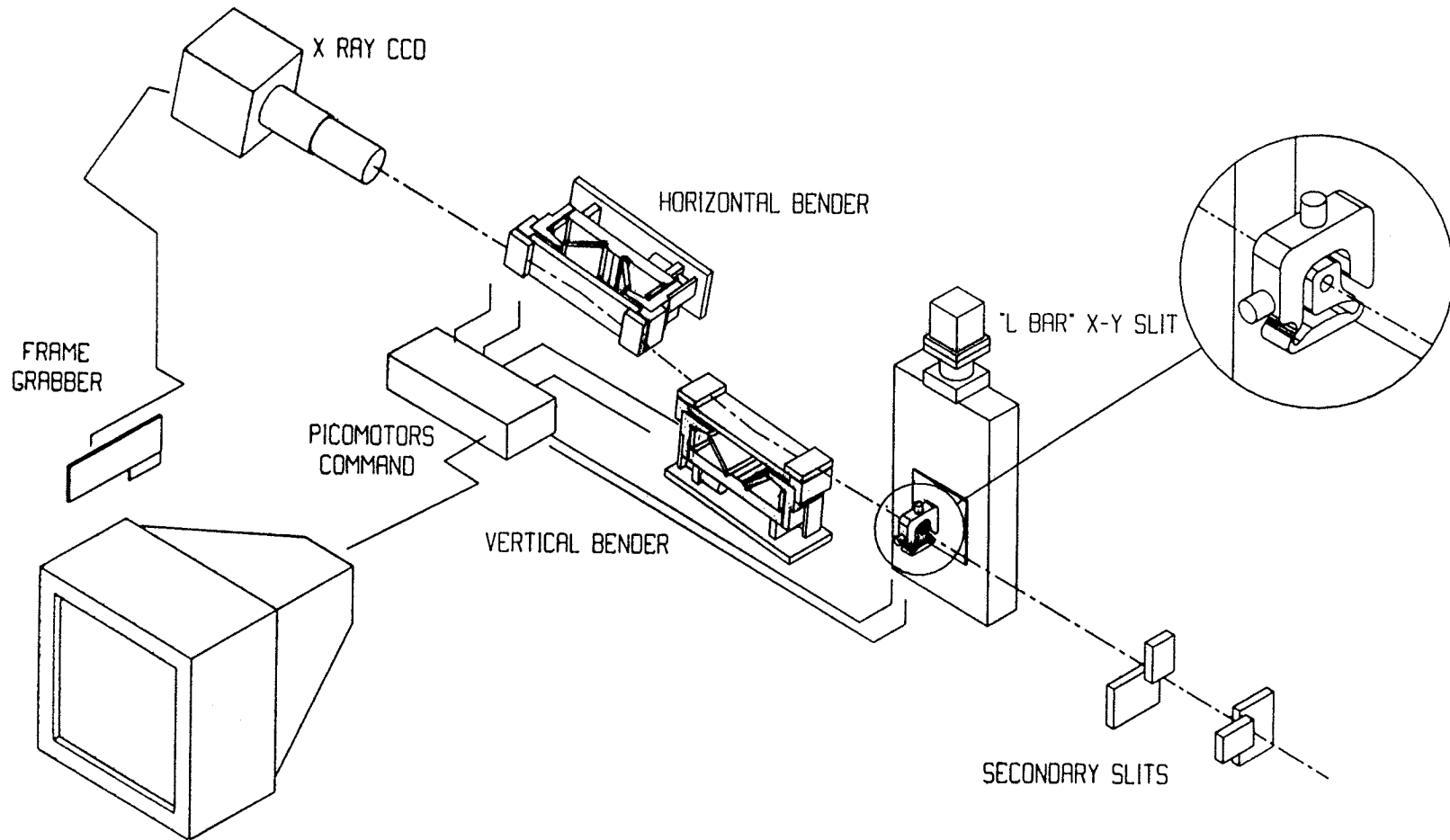
	KINEMATICAL FOCUSING BENT MIRROR OR CRYSTAL			DYNAMICAL FOCUSING			CAPILLARY OPTICS	FRESNEL OPTICS	BRAGG- FRESNEL OPTICS
				Indenbom 1974	Afanas'ev, Kohn 1977	Petrashen', Chukhovsky 1976	Kreger 1948	Baez 1952	Aristov et al 1986
	mirror	multilayer	crystal						
	Kirkpatrick, Baez 1948	Underwood, Barbee, Frieber 1986	Johann, Johansson 1931-1933						
angular aperture	10^{-3}	10^{-3}	10^{-4}	$10^{-4} - 10^{-5}$			10^{-3}		
resolution	$5\mu\text{m}$ Suzuki et al 1992	$5\mu\text{m}$ Underwood et al 1988	$10\mu\text{m}$ Van Lagevelde 1992	$<10\mu\text{m}$			0.05 Bilderback et al 1994	$0.6\mu\text{m}$ Yun et al 1992	0.5-0.7 Snigirev et al 1994-95

Finite element model of the flexural hinge-based bender

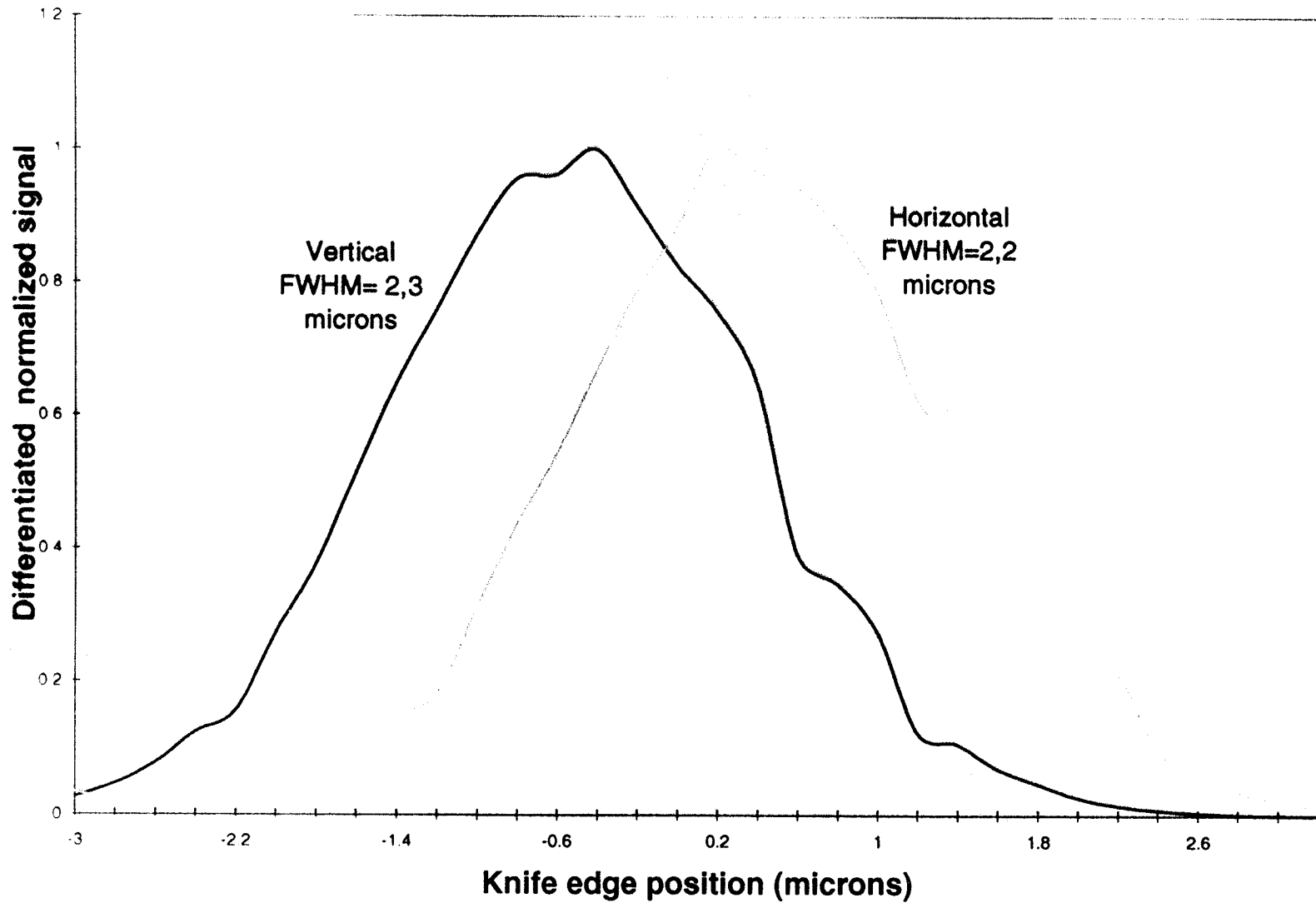


the piezo actuators are illustrated by 2 arrows
the triangles Δ represent fixations

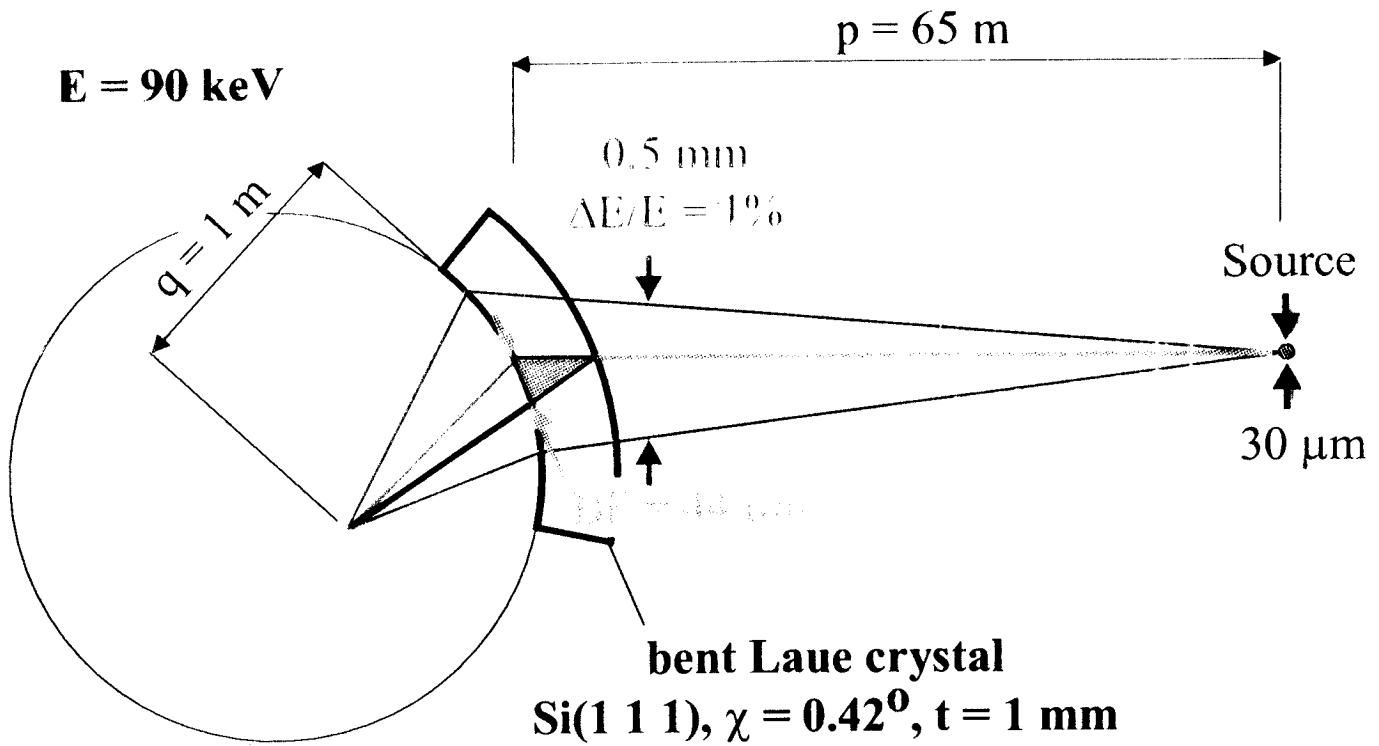
KIRPATRICK BAEZ AUTOMATED SHAPING



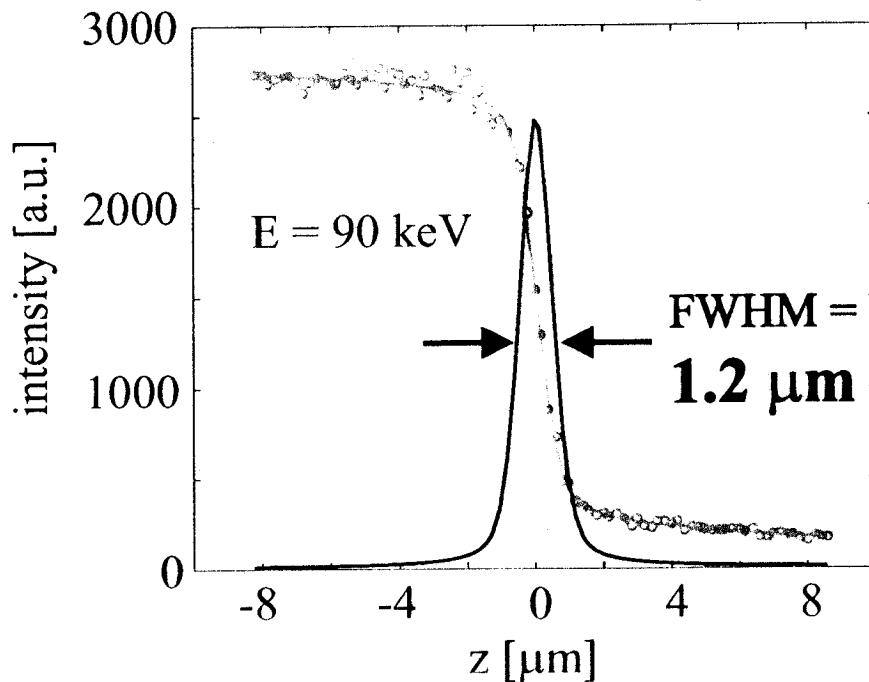
Bidirectional focusing on BM5 E = 9 KeV 800X800 microns Gain #10⁵



Laue focusing

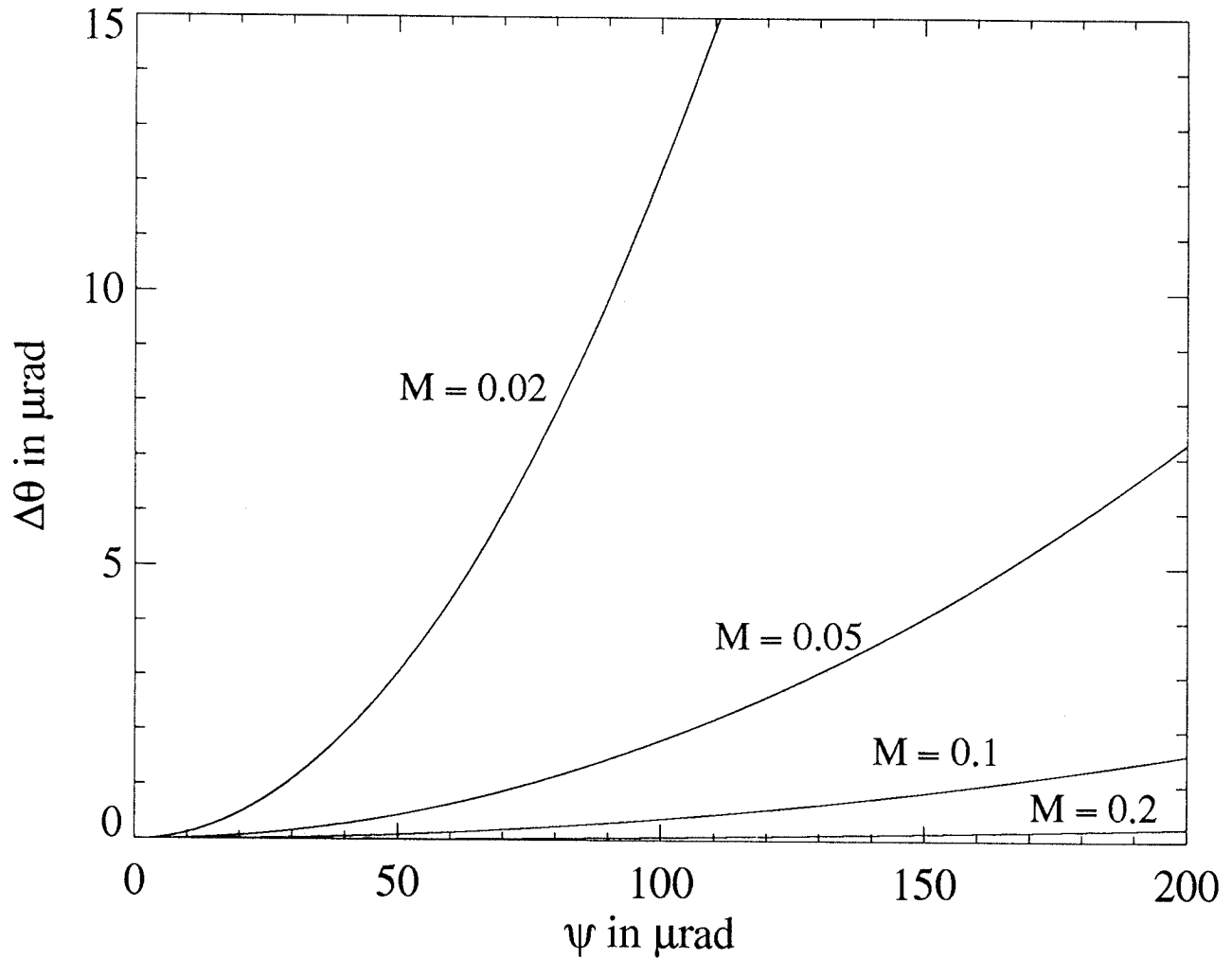


Fluorescence knife-edge scan

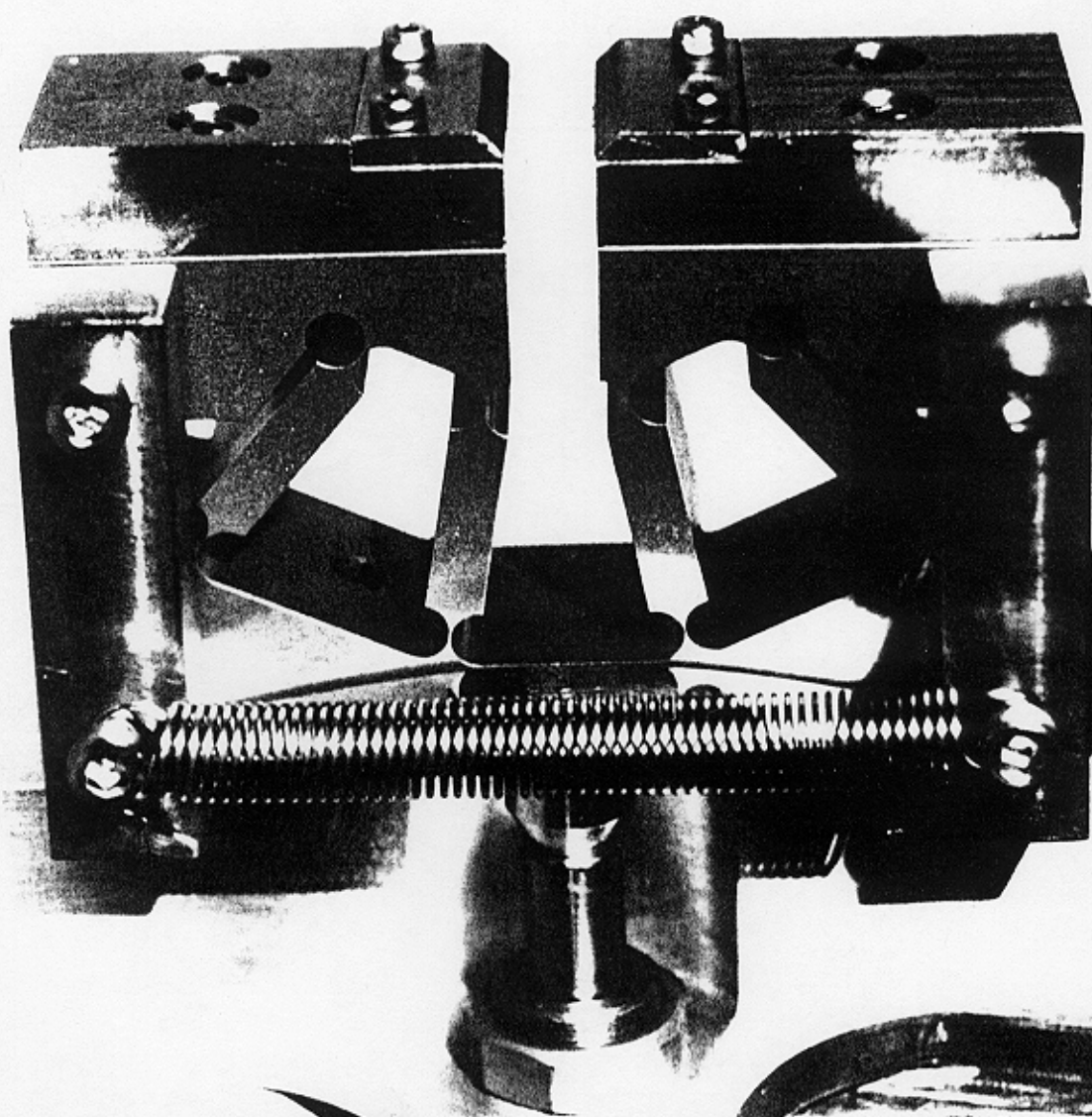


- flux in $1.2 \times 500 \mu\text{m}$:
 $4.3 \cdot 10^9 \text{ ph/s/0.1 A}$
- efficiency: 90 %
- gain factor: 300

$$\Delta\theta = \frac{\psi^2(1+M)(3M-1)}{8M^2 \sin\theta_B}$$

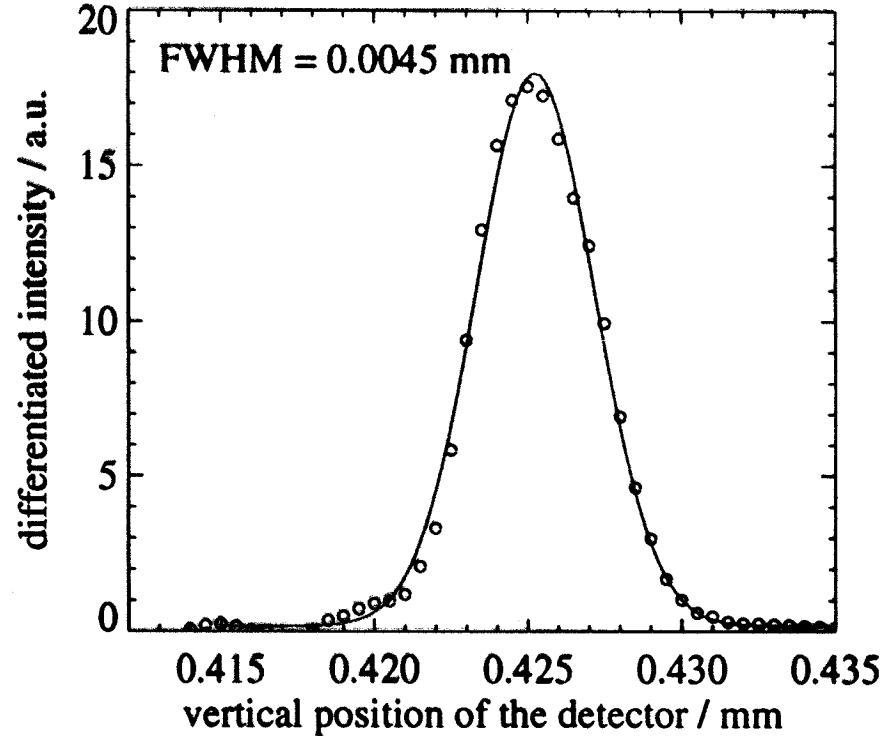
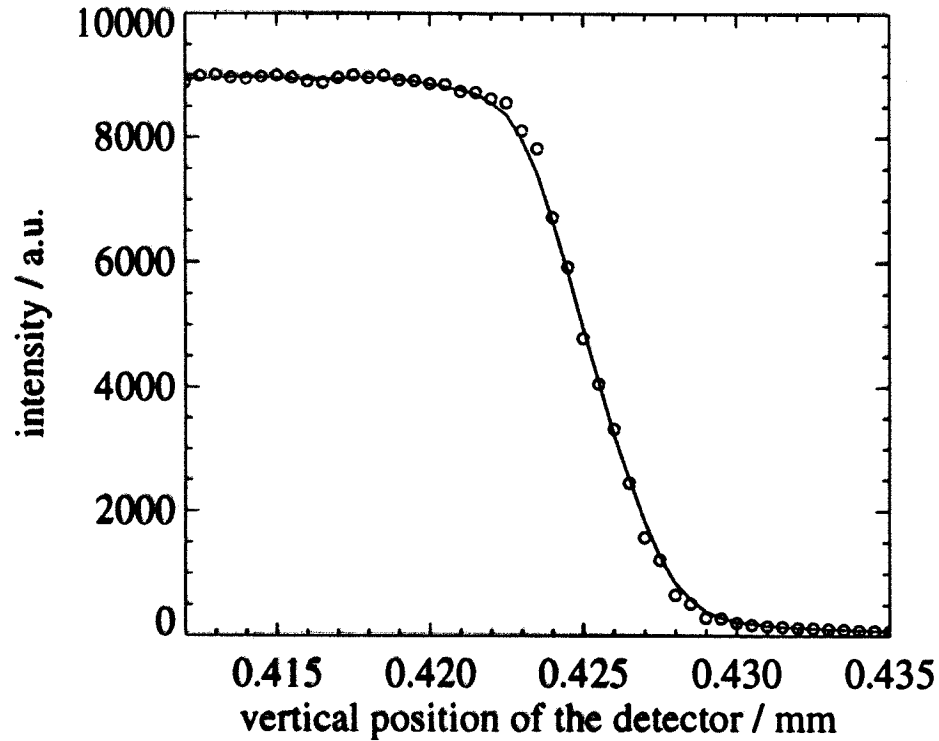


Angular errors in dependence of the divergence ψ , for different magnifications. Calculated for Si(111) and an energy of 8047.8 eV.



Focal spot, produced by a bent silicon[111] crystal

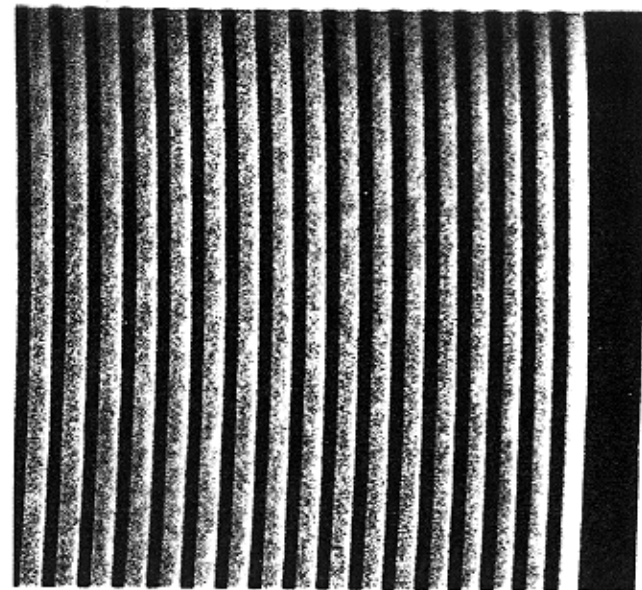
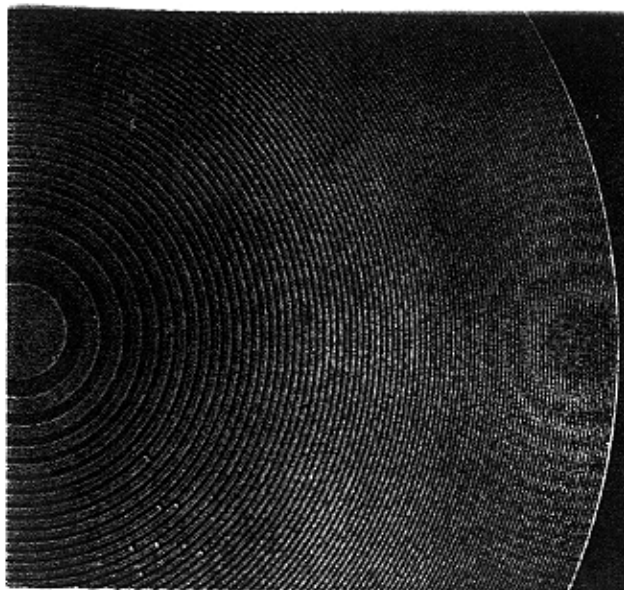
Knife edge scan; Energy = 8.047 keV



A. Freund et al., SPIE Proc. 1998

FZP

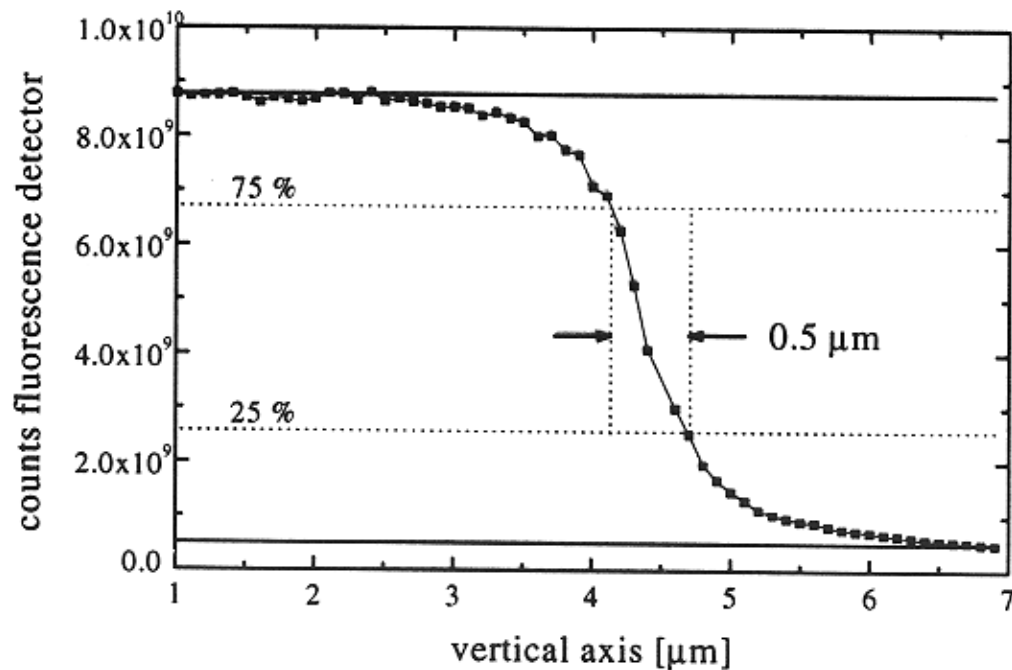
E.Di Fabrizio,
M. Gentili,
IESS, CNR, Rome, Italy



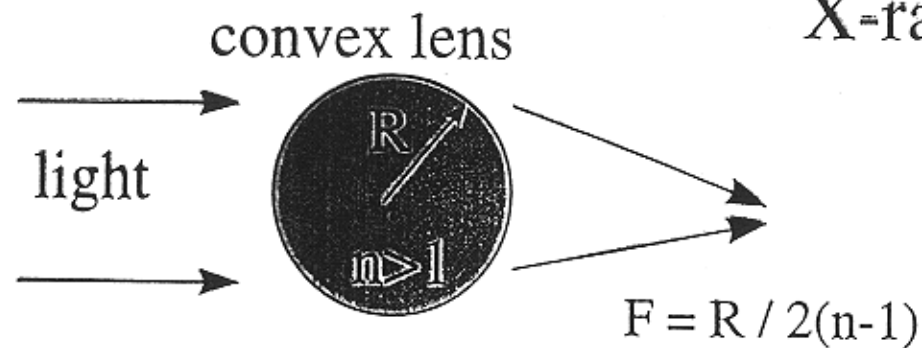
Cr-mask scan to resolve the spot size: $0.5 \mu\text{m}$ (V), $6 \mu\text{m}$ (H), flux 10^{10} ph/s

Fresnel zone plate parameters

169 zones, radius first zone: $7.8 \mu\text{m}$
radius last zone: $0.3 \mu\text{m}$
zone material: gold, thickness: $1.15 \mu\text{m}$
substrate: SiN, thickness: $2 \mu\text{m}$
aperture: $200 \mu\text{m}$
focal length 8 keV: 400 mm
12 keV: 600 mm

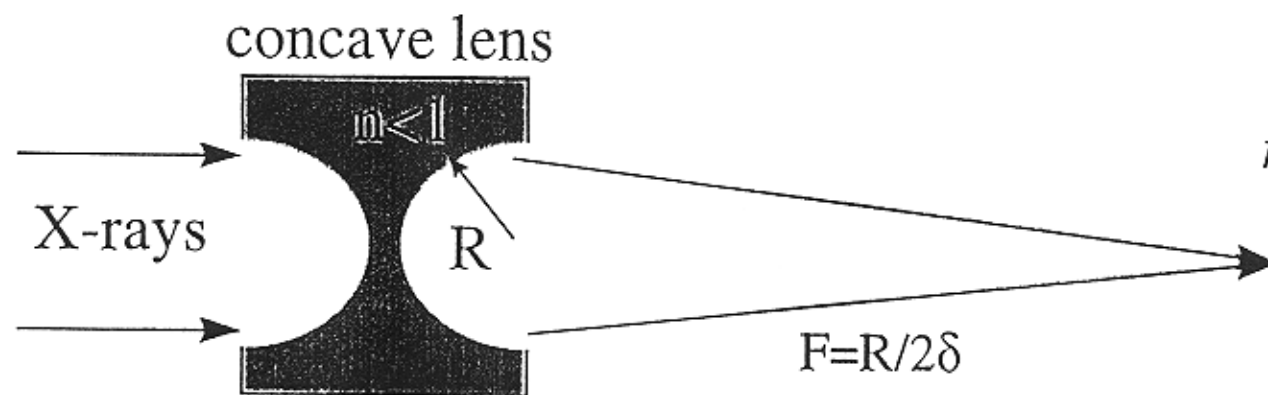


X-rays versus Light



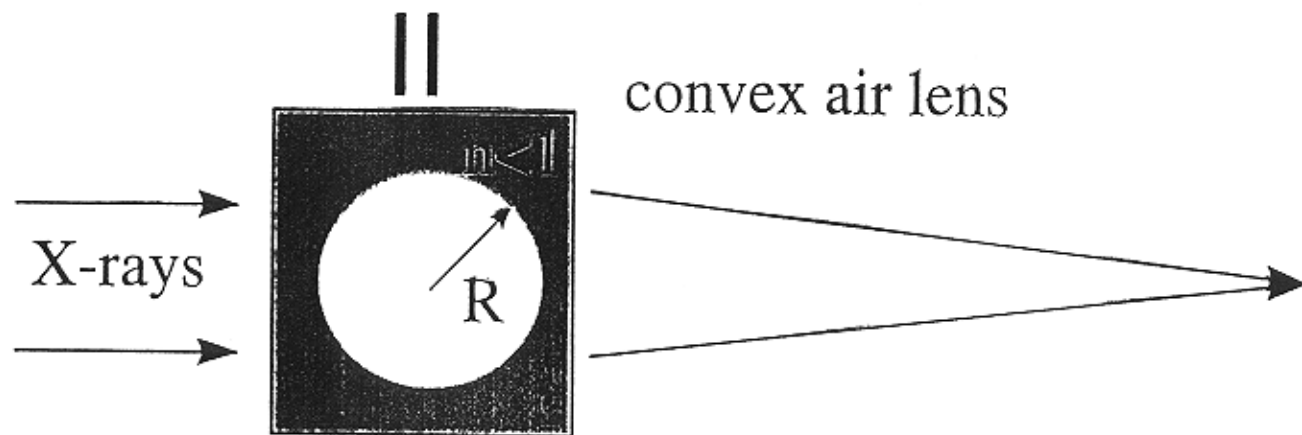
$$n > 1$$

$$n-1 \sim 0.1$$



$$n = 1 - \delta + i\beta < 1$$

$$1-n \sim 10^{-5}-10^{-6}$$



Be

$$E = 10 \text{ keV}$$

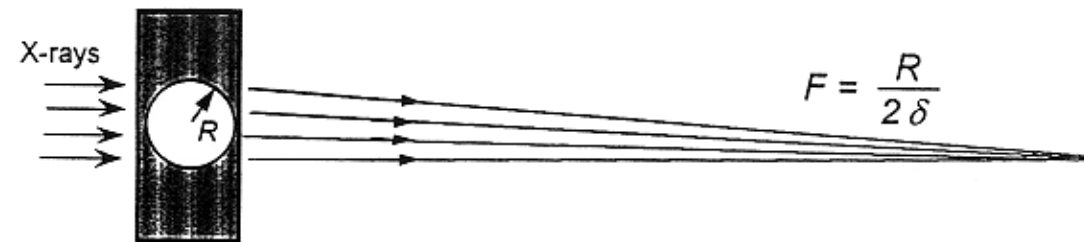
$$\delta = 3.4 \cdot 10^{-6}$$

$$R = 100 \mu\text{m}$$

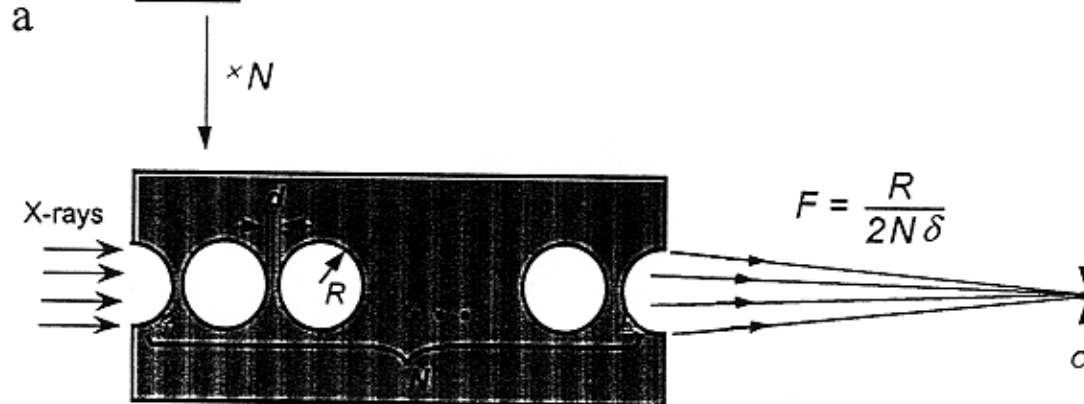
$$F = 15 \text{ m}$$

Compound Refractive Lens

Snigirev A., Kohn V., Snigireva I., Lengeler B., *Nature*, November 7, 1996



a



b

resolution

$$\sigma_f = \frac{\lambda r_f}{A}$$

effective aperture is limited by spherical aberrations or by absorption

$$A_t = 2R \left(4 \frac{\lambda r_f}{R^2} \right)^{\frac{1}{4}}$$

$$A_a = 2R \left(\frac{2}{\mu R N} \right)^{\frac{1}{2}}$$

real gain $g = a G \frac{\sigma_f}{\sigma_1} = a \frac{A}{\sigma_0} \left(\frac{r_0}{r_f} + 1 \right)$, where $a = \exp(-\mu N d)$, $\sigma_1 = \sigma_0 r_f / r_0$

chromatic aberrations

$$\frac{\Delta \lambda}{\lambda} \approx \frac{\beta}{\delta}$$

index of refraction

$$n = 1 - \delta + i\beta < 1 \quad (\delta > 0),$$

X-ray collecting lens has a **concave shape**

for Al at E = 10 keV $\delta = 0.55 \cdot 10^{-5}$

1 hole of 100 μm radius - F = 9 m

15 holes of 100 μm radius - F = 60 cm

Gaussian lens formula: $r_f = F \left(1 - \frac{F}{r_0} \right)^{-1}$

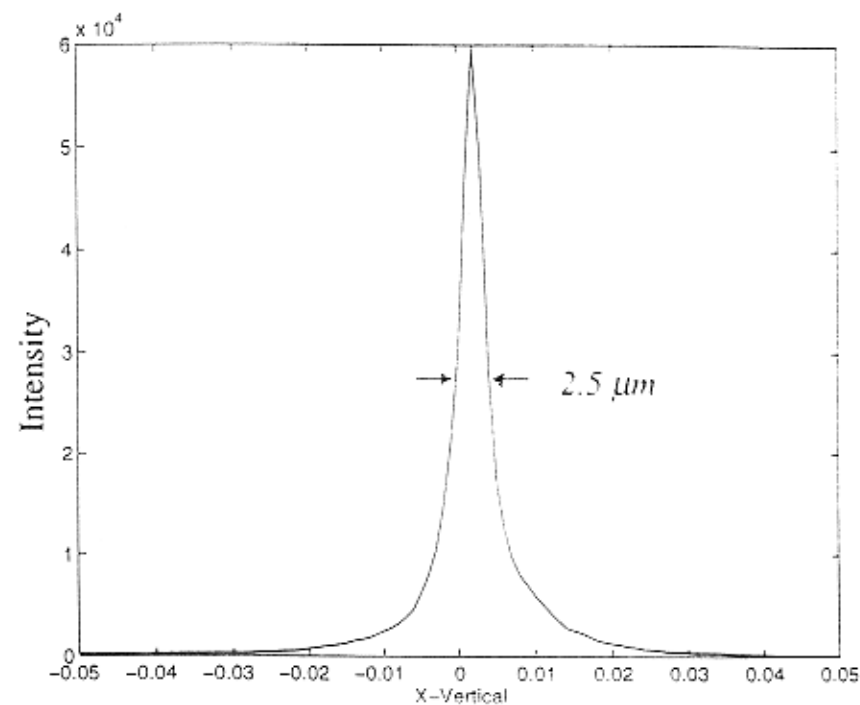
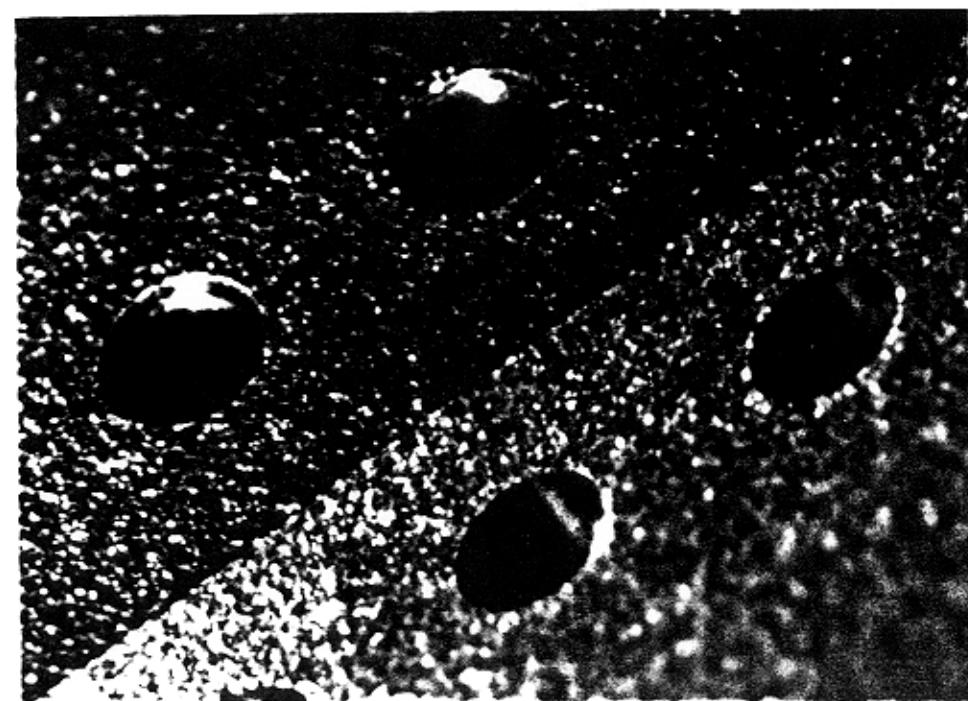
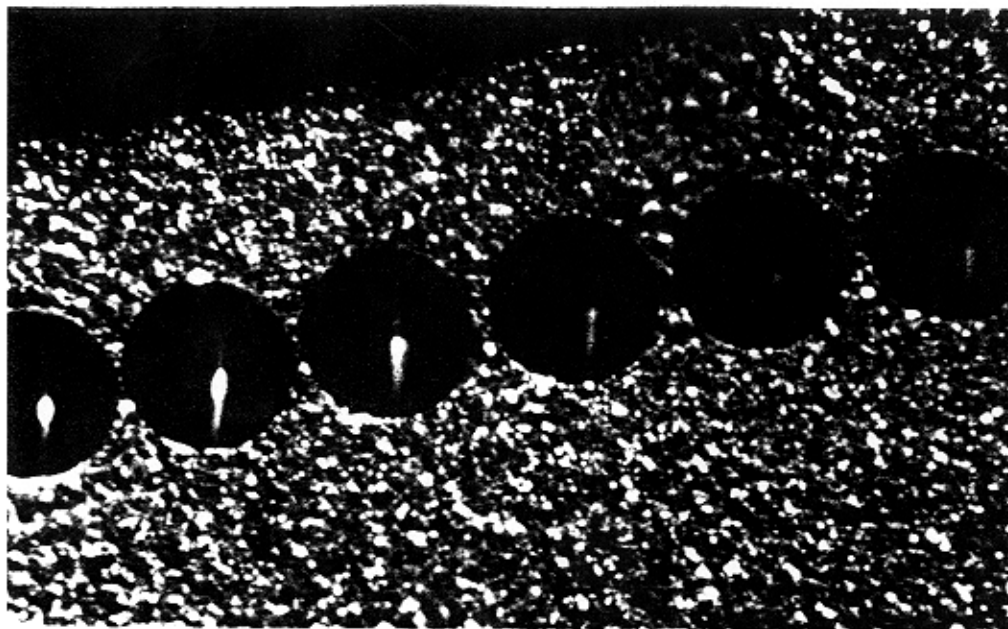


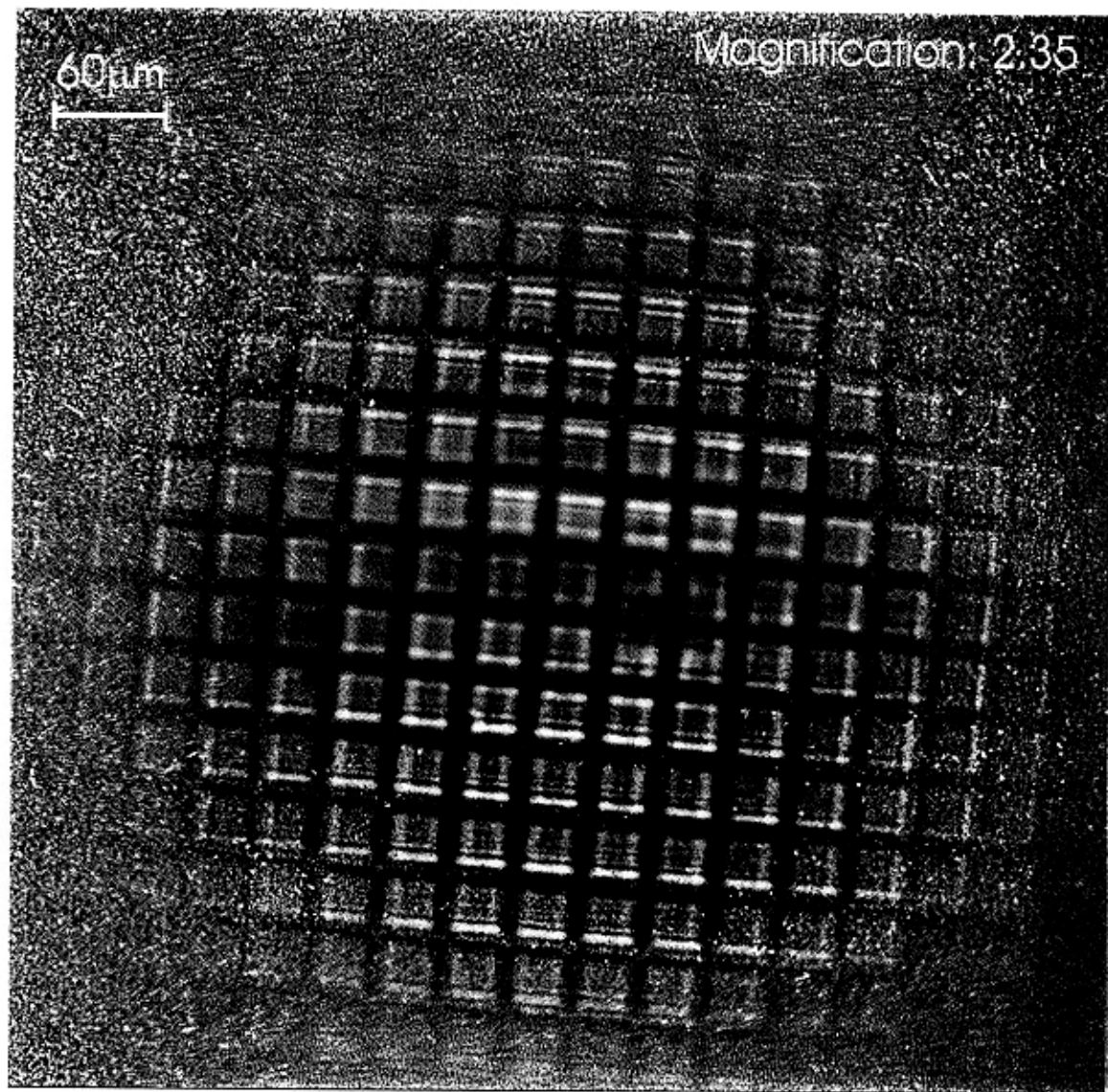
Image in optical microscope of linear and two-dimensional Be CRLs with 69 holes of 500 μm diameter. Spacing in the thinner part between holes is about 100 μm .

Intensity distribution of the focal spot at 0.9 m focal distance for Be CRL at 9 keV X-ray energy. Width of the focusing line was measured of about 2.5 μm and was limited by the source size.

Optical properties of cylindrical CRLs. Experimental results.

Material	Hole radius, R (mm)	Distance between the holes, d (μm)	Energy, E keV	Focal length, F (m)	Number of holes, N	Spot size (FWHM), (vert./hor.) Δ (μm)	Gain, g
<i>Be</i>	0.50	100	12.6	1.7	69	3.4	5.7
<i>Be</i>	0.50	100	9.0	0.87	60	2.6	2.0
<i>Be</i>	0.25	20	12.5	1.09	53	3.3	9.0
<i>Be crossed</i>	0.50	50	9.2	1.82	36.5/37	7.6/19	13.6
<i>Boron Nitride</i>	0.25	50	12.5	1.64	39	-	-
<i>Pyrocarbon</i>	0.35	39	16.4	1.70	59	4.2	12.6
<i>Teflon</i>	0.35	38	23.7	1.78	134	11.0	1.0
<i>Teflon crossed</i>	0.35	38	16.7	1.83	67/67	5.2/18	0.8
<i>PMMA</i>	0.25	30	12.5	1.27	59	10.0	4.5
<i>Polycarbonate</i>	0.25	50	12.5	1.88	40	4.9	6.5
<i>Polyoxymethylene</i>	0.25	30	12.5	1.61	40	3.5	4.4
<i>Vespel</i>	0.25	30	12.5	1.28	50	5.0	1.9
<i>Al (0.5%Mg))</i>	0.50	38	18.8	1.70	96	3.5	1.3
<i>Al(2x)</i>	0.50	38/40	27.1	1.70	192	4.5	1.3

Imaging of a gold grid (15 μm period) by X-ray refractive lens at 15 keV



B. Lengeler, M. Richwin, C. Schroer, J. Tümmeler,
RWTH Aachen

A. Snigirev, I. Snigireva,
ESRF, Grenoble

Fresnel diffraction on the slits / ID22

A. Snigirev, I. Snigireva, V. Kohn, C. Raven (ESRF)

full beam (1 mm)



primary slits (14 m)



200 μm



150/100 μm

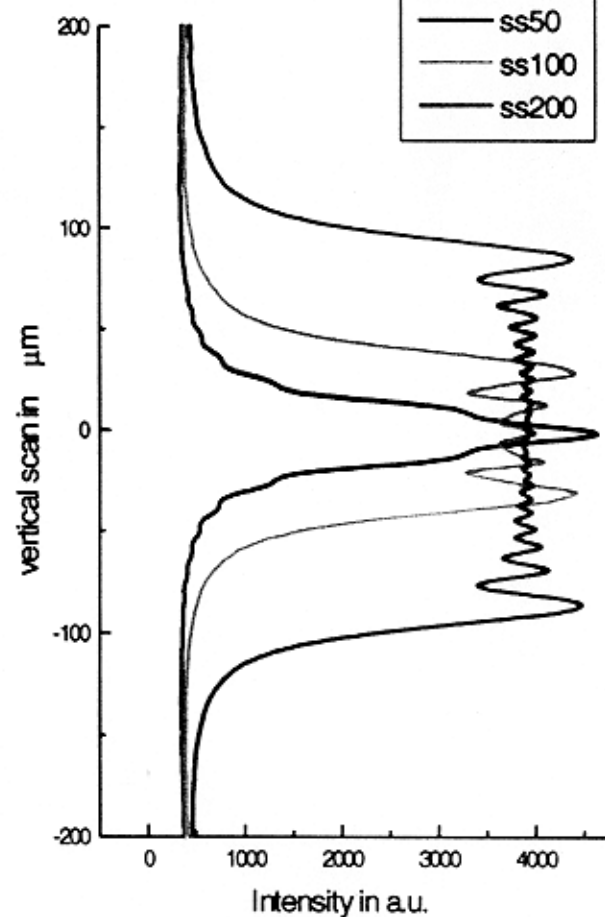


50 μm

secondary slits (4.5 m)



vertical beam intensity
with secondary slits closed to



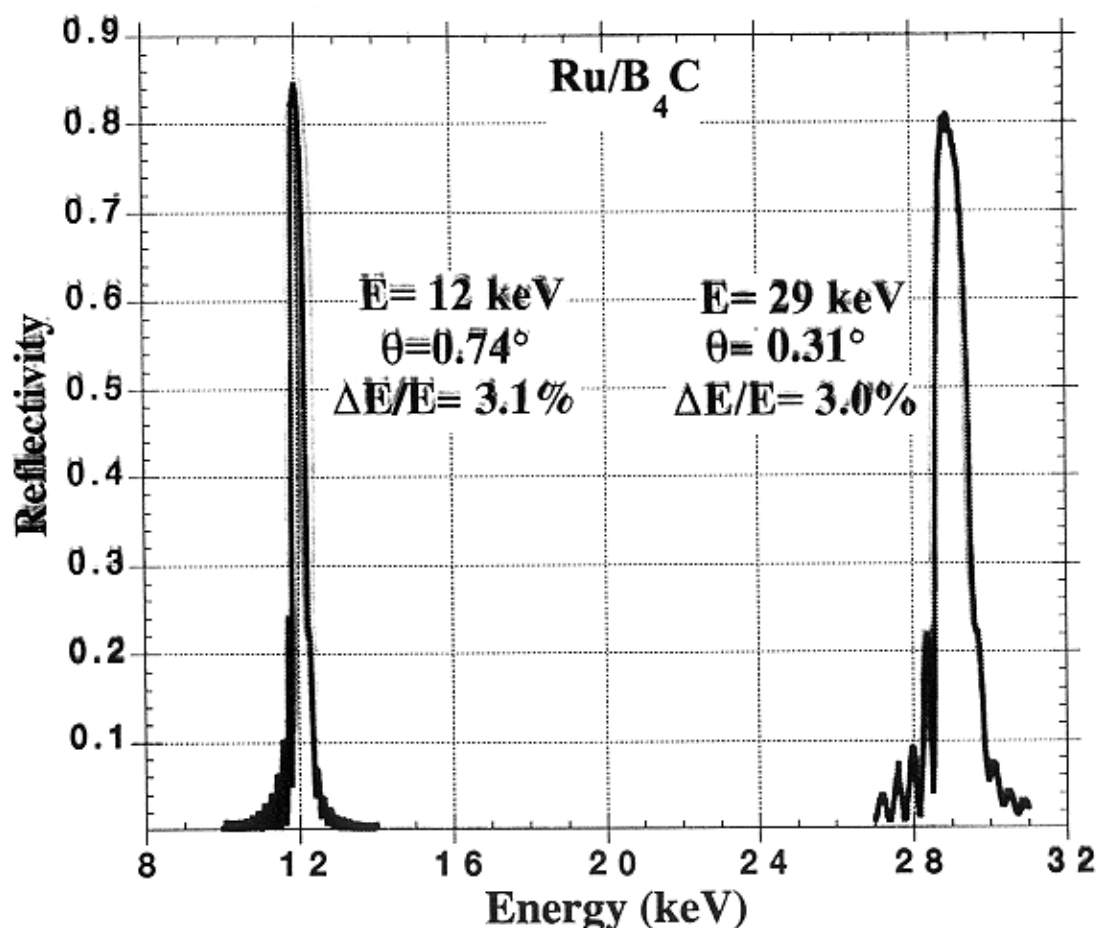
MULTILAYER CHARACTERISTICS

Courtesy: E. FIEGLER, Ch. MORAWE (ESRF)

[Ru/B₄C]65 d-spacing: 4.19 nm

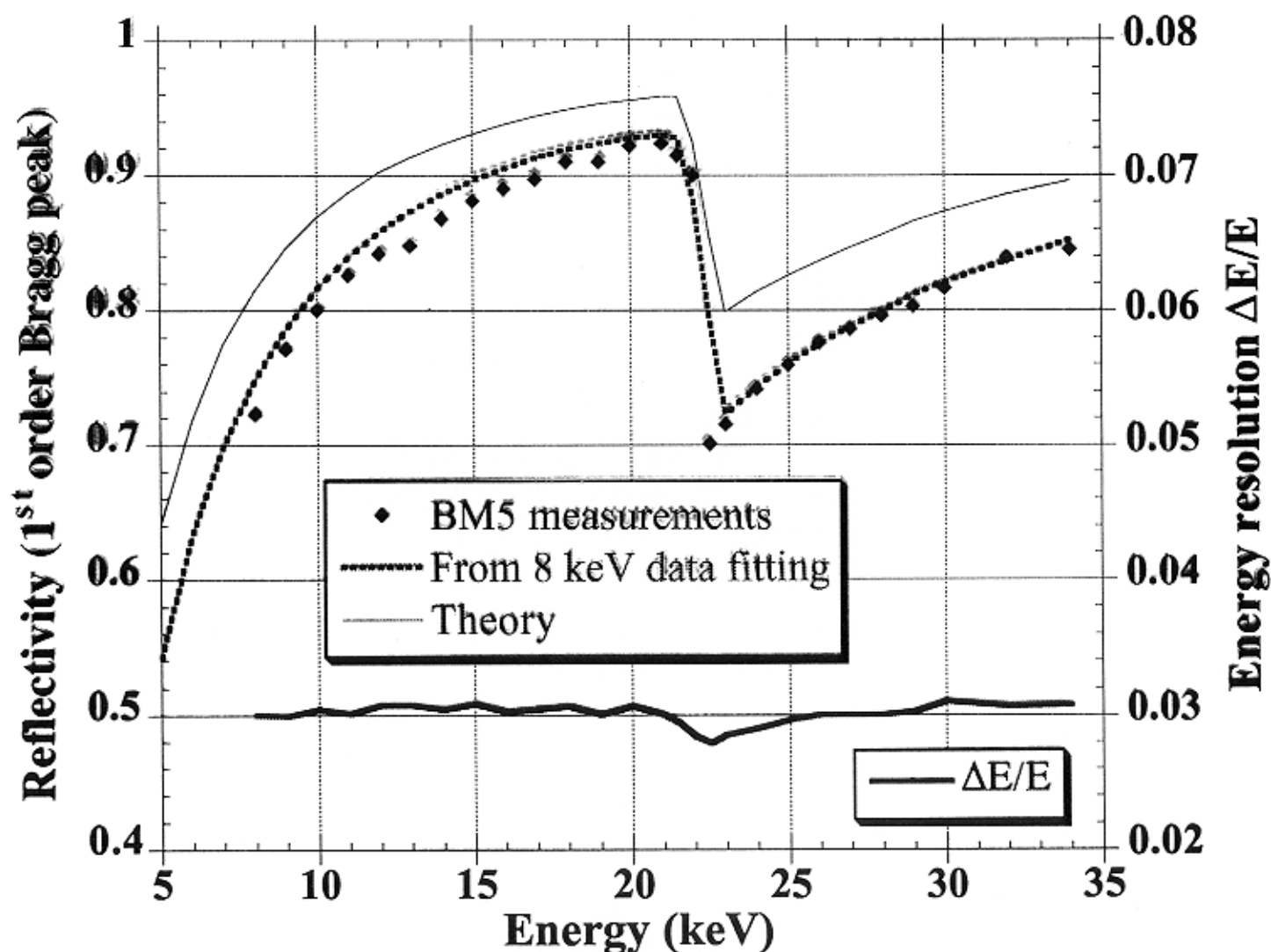
manufactured at ESRF02

interface roughness: $\sigma_{\text{rms}}=0.25$ nm

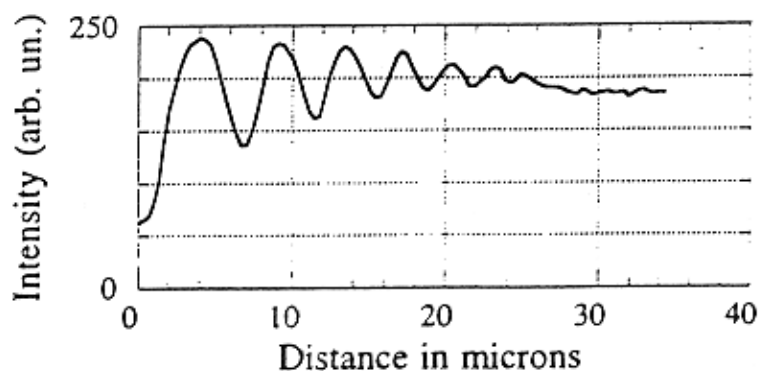
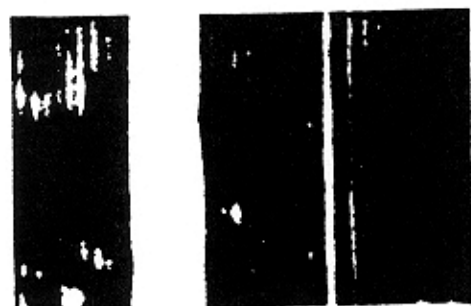
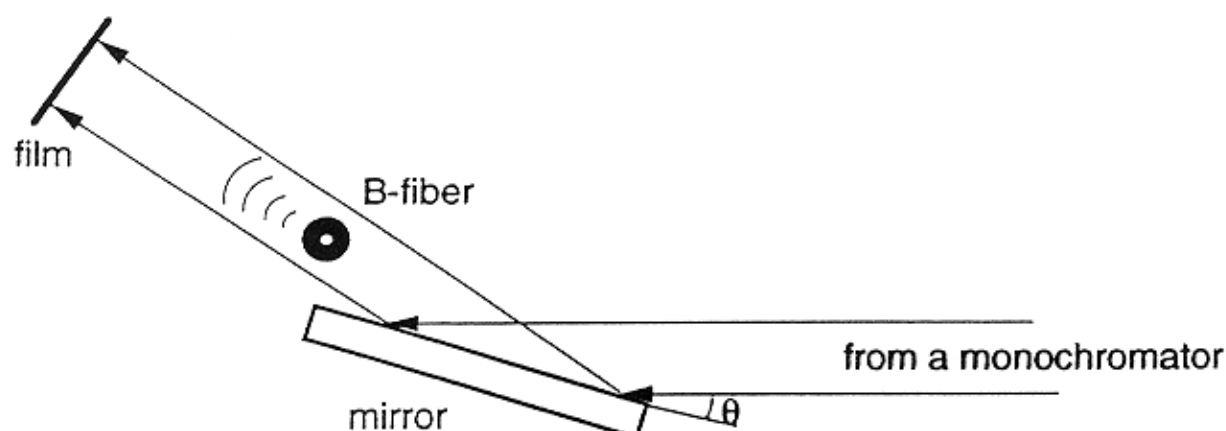
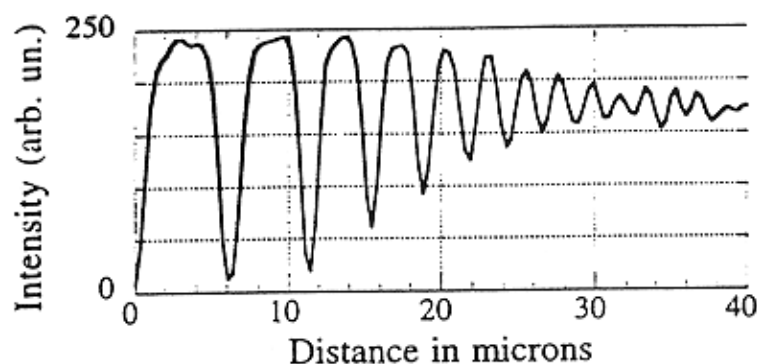
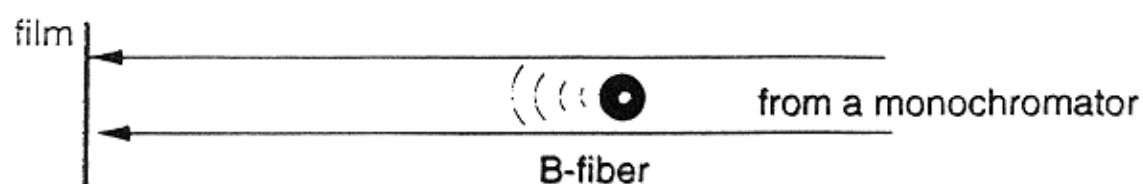


MULTILAYER PERFORMANCE vs ENERGY

Courtesy: E. ZIEGLER, Ch. MORAWS (ESRF)

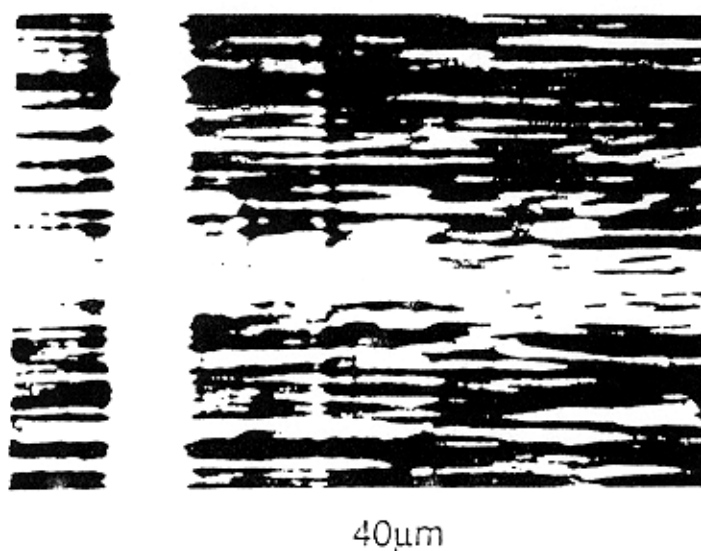
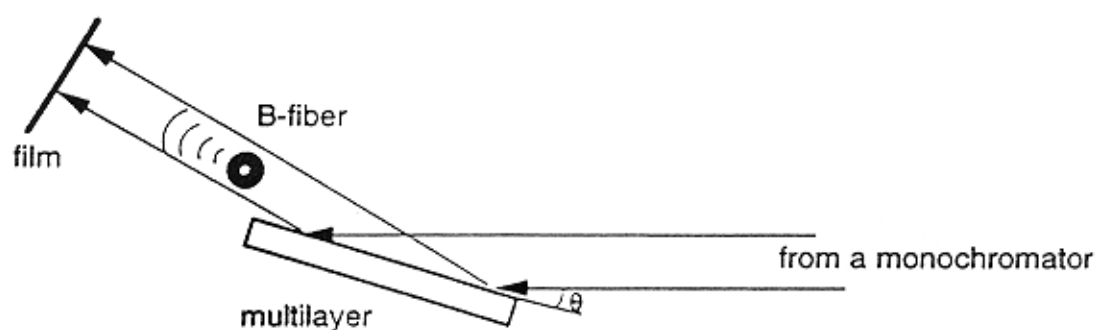
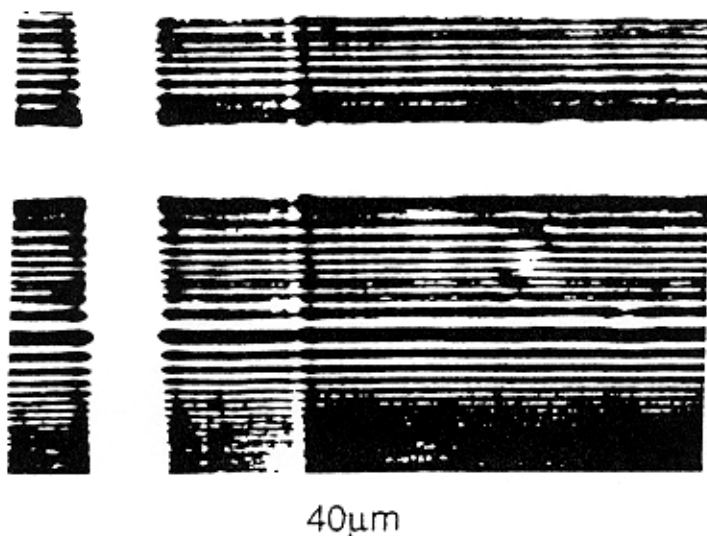
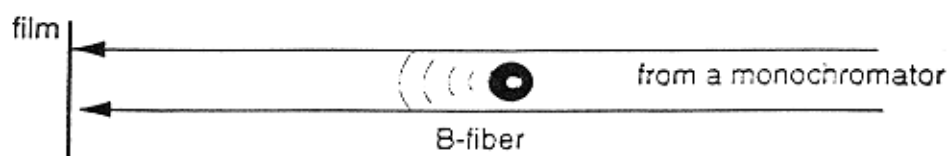


$E=10\text{keV}$
 B-fiber $\varnothing 100\mu\text{m}$ (W-core $\varnothing 15\mu\text{m}$)
 fiber-to-film distance 50cm



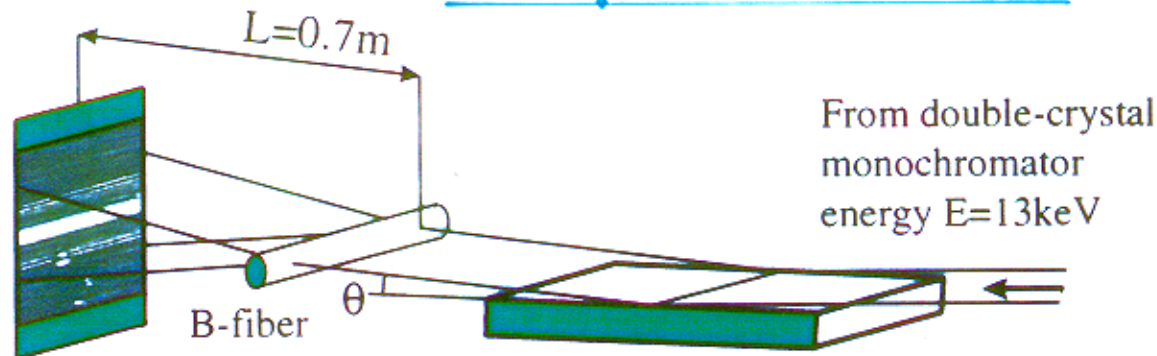
40 μm

B-fiber $\varnothing 100\mu\text{m}$ (W-core $\varnothing 15\mu\text{m}$)
 fiber-to-film distance 50cm
 W-Si multilayer $d=35\text{\AA}$



Snigirev et al., 1995.

Courtesy: A. SOUVOROV (ESRF)

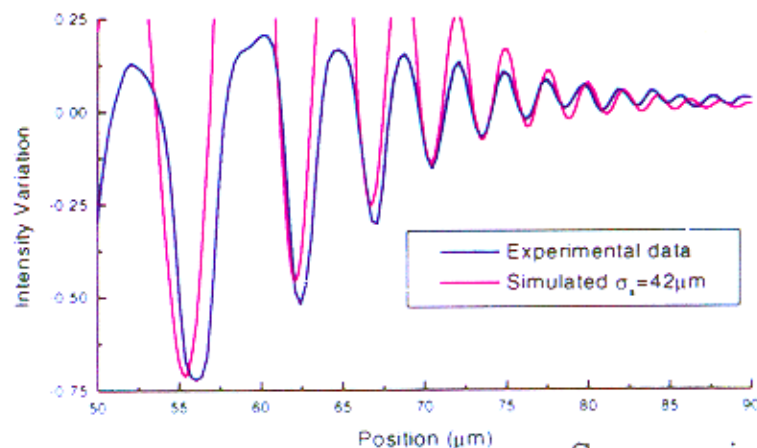
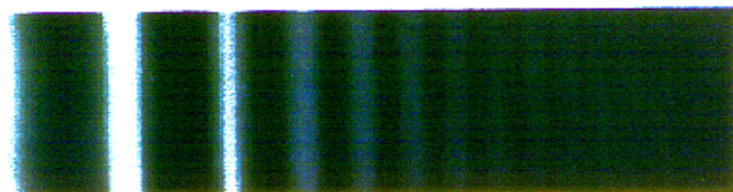


Ru/B₄C multilayer
period $D=4\text{nm}$, angle $\theta=0.69^\circ$
number of layers $N=60$
Length/Width $100\times 25\text{mm}$

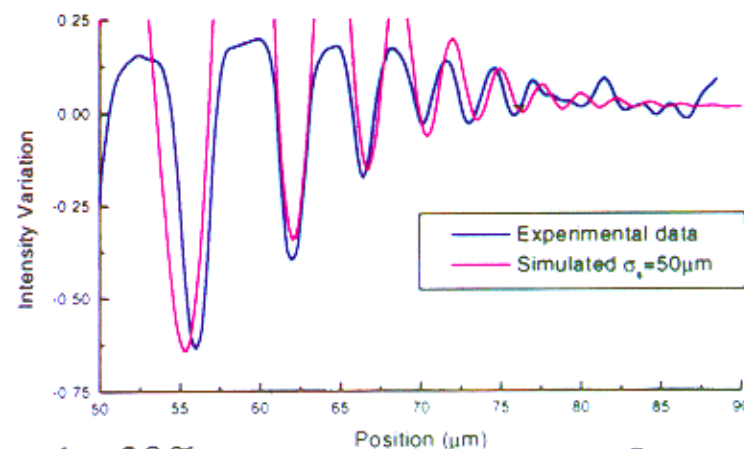
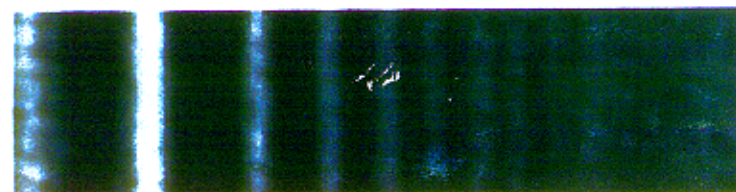
Intensity RMS~10.4%



Incident beam

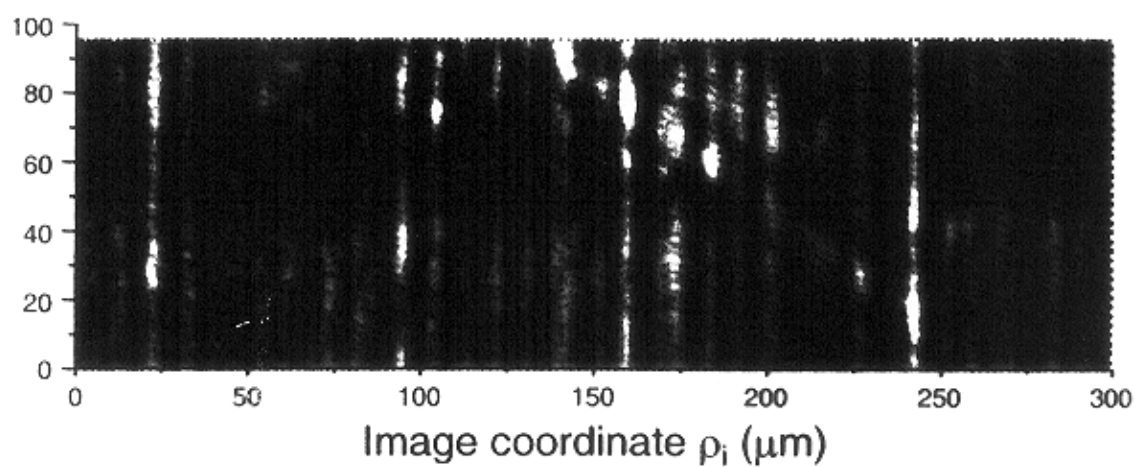


Reflected beam

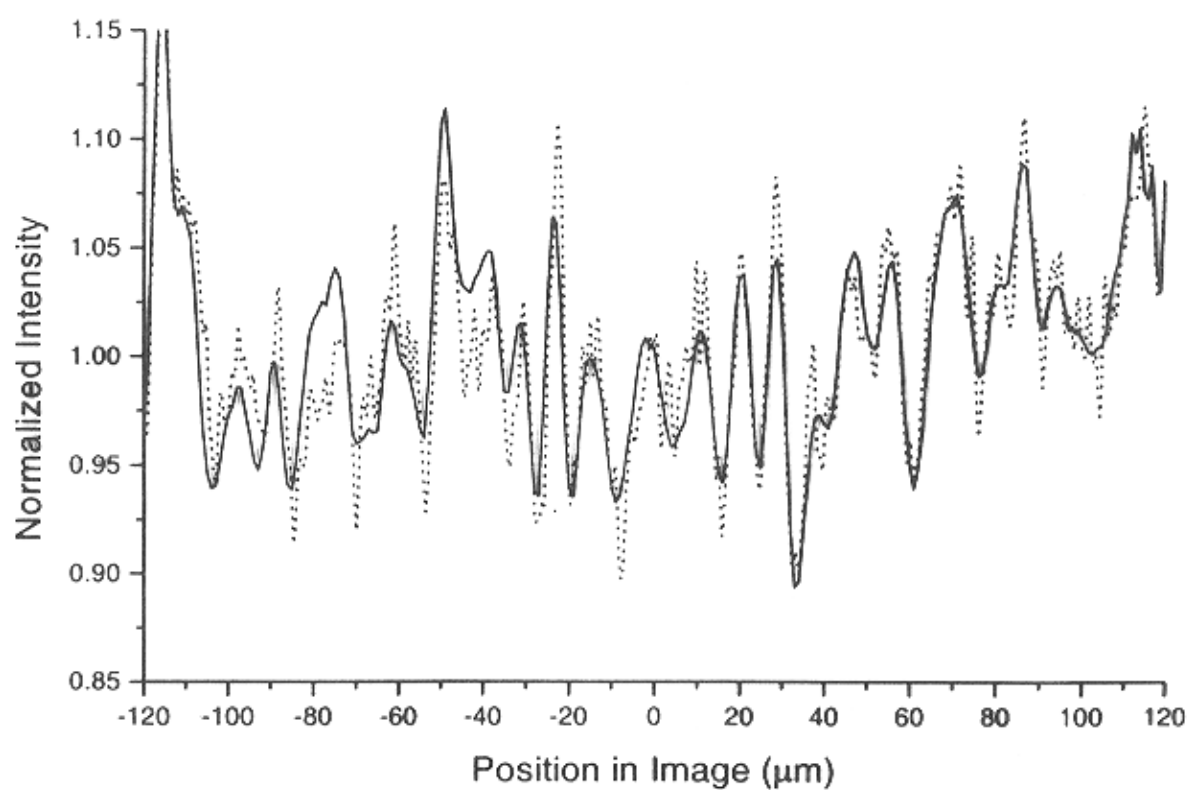


Source size increment by 20%

Souvorov A.



a)



b)

Figure 3